#### Freescale Semiconductor

Data Sheet: Technical Data

Document Number: MPC5534

Rev. 5, Oct 2010

# MPC5534 Microcontroller Data Sheet

by: Microcontroller Division

This document provides electrical specifications, pin assignments, and package diagrams for the MPC5534 microcontroller device. For functional characteristics, refer to the MPC5534 Microcontroller Reference Manual.

#### 1 Overview

The MPC5534 microcontroller (MCU) is a member of the MPC5500 family of microcontrollers built on the Power Architecture<sup>TM</sup> embedded technology. This family of parts has many new features coupled with high performance CMOS technology to provide substantial reduction of cost per feature and significant performance improvement over the MPC500 family.

The host processor core of this device complies with the Power Architecture embedded category that is 100% user-mode compatible (including floating point library) with the original Power PC<sup>TM</sup> user instruction set architecture (UISA). The embedded architecture enhancements improve the performance in embedded applications. The core also has additional instructions, including digital signal processing (DSP) instructions, beyond the original Power PC instruction set.

#### **Contents**

| 1 | Ove  | rview   | . 1 |
|---|------|---|-----|
| 2 | Ord  | ering Information                               | . 3 |
| 3 | Elec | etrical Characteristics                         | . 4 |
|   | 3.1  | Maximum Ratings                                 | . 4 |
|   | 3.2  | Thermal Characteristics                         | . 5 |
|   | 3.3  | Package   | . 8 |
|   | 3.4  | EMI Characteristics                             | . 8 |
|   | 3.5  | ESD Characteristics                             | . 9 |
|   | 3.6  | VRC and POR Electrical Specifications           |     |
|   | 3.7  | Power-Up/Down Sequencing                        |     |
|   | 3.8  | DC Electrical Specifications                    | 13  |
|   | 3.9  | Oscillator and FMPLL Electrical Characteristics | 20  |
|   | 3.10 | eQADC Electrical Characteristics                |     |
|   | 3.11 | H7Fb Flash Memory Electrical Characteristics    | 23  |
|   | 3.12 | AC Specifications                               | 24  |
|   | 3.13 | AC Timing                                       | 26  |
| 4 | Med  | chanicals                                       | 46  |
|   | 4.1  | MPC5534 208 MAP BGA Pinout                      | 46  |
|   | 4.2  | MPC5534 324 PBGA Pinouts                        | 47  |
|   | 4.3  | MPC5534 208-Pin Package Dimensions              | 48  |
|   | 4.4  | MPC5534 324-Pin Package Dimensions              | 50  |
| 5 | Rev  | ision History for the MPC5534 Data Sheet        | 52  |
|   | 5.1  | Changes Between Revisions 4.0 and 5.0           | 52  |
|   | 5.2  | Changes Between Revisions 3.0 and 4.0           | 52  |

© Freescale Semiconductor, Inc., 2008, 2010. All rights reserved.



#### Overview

The MPC5500 family of parts contains many new features coupled with high performance CMOS technology to provide significant performance improvement over the MPC565.

The host processor core of the MPC5534 also includes an instruction set enhancement allowing variable length encoding (VLE). This allows optional encoding of mixed 16- and 32-bit instructions. With this enhancement, it is possible to significantly reduce the code size footprint.

The MPC5534 has a single-level memory hierarchy consisting of 64-kilobytes (KB) on-chip SRAM and one megabyte (MB) of internal flash memory. Both the SRAM and the flash memory can hold instructions and data. The external bus interface (EBI) supports most standard memories used with the MPC5xx family.

The MPC5534 does not support arbitration with other masters on the external bus. The MPC5534 must be the only master on the external bus, or act as a slave-only device.

The complex input/output timer functions of the MPC5534 are performed by an enhanced time processor unit (eTPU) engine. The eTPU engine controls 32 hardware channels. The eTPU has been enhanced over the TPU by providing: 24-bit timers, double-action hardware channels, variable number of parameters per channel, angle clock hardware, and additional control and arithmetic instructions. The eTPU is programmed using a high-level programming language.

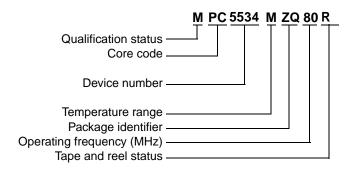
The less complex timer functions of the MPC5534 are performed by the enhanced modular input/output system (eMIOS). The eMIOS' 24 hardware channels are capable of single-action, double-action, pulse-width modulation (PWM), and modulus-counter operations. Motor control capabilities include edge-aligned and center-aligned PWM.

Off-chip communication is performed by a suite of serial protocols including controller area networks (FlexCANs), enhanced deserial/serial peripheral interfaces (DSPIs), and enhanced serial communications interfaces (eSCIs).

The MCU has an on-chip enhanced queued dual analog-to-digital converter (eQADC) with a 5 V conversion range. The 324 package has 40-channels; the 208 package has 34 channels.

The system integration unit (SIU) performs several chip-wide configuration functions. Pad configuration and general-purpose input and output (GPIO) are controlled from the SIU. External interrupts and reset control are also determined by the SIU. The internal multiplexer sub-block (IMUX) provides multiplexing of eQADC trigger sources and external interrupt signal multiplexing.

# **Ordering Information**



**Temperature Range** 

Package Identifier

**Operating Frequency** 

**Tape and Reel Status** 

 $M = -40^{\circ} C \text{ to } 125^{\circ} C$ 

VF = 208MAPBGA SnPb VM = 208MAPBGA Pb-free

40 = 40 MHz66 = 66 MHz

R = Tape and reel (blank) = Trays

ZQ = 324PBGA SnPb VZ = 324PBGA Pb-free 80 = 80 MHz

**Qualification Status** 

P = Pre qualification

Note: Not all options are available on all devices. Refer to Table 1.

M = Fully spec. qualified, general market flow S = Fully spec. qualified, automotive flow

Figure 1. MPC5500 Family Part Number Example

Unless noted in this data sheet, all specifications apply from  $T_L$  to  $T_H$ .

**Table 1. Orderable Part Numbers** 

| Freescale Part Number | Package Description                       | Spee    | Speed (MHz)                           |           | mperature <sup>1</sup> |
|-----------------------|---|---------|---------------------------------------|-----------|------------------------|
| Treescale Fait Number | Package Description                       | Nominal | Max. <sup>2</sup> (f <sub>MAX</sub> ) | Min. (T∟) | Max. (T <sub>H</sub> ) |
| MPC5534MVZ80          |   | 80      | 82                                    |           |                        |
| MPC5534MVZ66          | MPC5534 324 package<br>Lead-free (PbFree) | 66      | 68                                    | −40° C    | 125° C                 |
| MPC5534MVZ40          | 2544 1165 (1 51 166)                      | 40      | 42                                    |           |                        |
| MPC5534MVM80          |   | 80      | 82                                    |           |                        |
| MPC5534MVM66          | MPC5534 208 package<br>Lead-free (PbFree) | 66      | 68                                    | −40° C    | 125° C                 |
| MPC5534MVM40          | 2544 1165 (1 51 166)                      | 40      | 42                                    |           |                        |
| MPC5534MZQ80          |   | 80      | 82                                    |           |                        |
| MPC5534MZQ66          | MPC5534 324 package<br>Leaded (SnPb)      | 66      | 68                                    | −40° C    | 125° C                 |
| MPC5534MZQ40          | 250000 (5111 5)                           | 40      | 42                                    |           |                        |
| MPC5534MVF80          |   | 80      | 82                                    |           |                        |
| MPC5534MVF66          | MPC5534 208 package<br>Leaded (SnPb)      | 66      | 68                                    | −40° C    | 125° C                 |
| MPC5534MVF40          | (• •)                                     | 40      | 42                                    |           |                        |

The lowest ambient operating temperature is referenced by T<sub>I</sub>; the highest ambient operating temperature is referenced by T<sub>H</sub>.

Speed is the nominal maximum frequency. Max. speed is the maximum speed allowed including frequency modulation (FM). 42 MHz parts allow for 40 MHz system clock + 2% FM; 68 MHz parts allow for 66 MHz system clock + 2% FM, and 82 MHz parts allow for 80 MHz system clock + 2% FM.

This section contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications for the MCU.

# 3.1 Maximum Ratings

Table 2. Absolute Maximum Ratings <sup>1</sup>

| Spec | Characteristic  | Symbol                               | Min.                                | Max.                                 | Unit |
|------|---|--------------------------------------|-------------------------------------|--------------------------------------|------|
| 1    | 1.5 V core supply voltage <sup>2</sup>  | $V_{DD}$                             | -0.3                                | 1.7                                  | V    |
| 2    | Flash program/erase voltage   | $V_{PP}$                             | -0.3                                | 6.5                                  | V    |
| 4    | Flash read voltage  | V <sub>FLASH</sub>                   | -0.3                                | 4.6                                  | V    |
| 5    | SRAM standby voltage  | V <sub>STBY</sub>                    | -0.3                                | 1.7                                  | V    |
| 6    | Clock synthesizer voltage   | V <sub>DDSYN</sub>                   | -0.3                                | 4.6                                  | V    |
| 7    | 3.3 V I/O buffer voltage  | V <sub>DD33</sub>                    | -0.3                                | 4.6                                  | V    |
| 8    | Voltage regulator control input voltage   | V <sub>RC33</sub>                    | -0.3                                | 4.6                                  | V    |
| 9    | Analog supply voltage (reference to V <sub>SSA</sub> )  | $V_{DDA}$                            | -0.3                                | 5.5                                  | V    |
| 10   | I/O supply voltage (fast I/O pads) <sup>3</sup>   | $V_{DDE}$                            | -0.3                                | 4.6                                  | V    |
| 11   | I/O supply voltage (slow and medium I/O pads) <sup>3</sup>  | $V_{DDEH}$                           | -0.3                                | 6.5                                  | V    |
| 12   | DC input voltage <sup>4</sup> V <sub>DDEH</sub> powered I/O pads  V <sub>DDE</sub> powered I/O pads | V <sub>IN</sub>                      | -1.0 <sup>5</sup> -1.0 <sup>5</sup> | 6.5 <sup>6</sup><br>4.6 <sup>7</sup> | V    |
| 13   | Analog reference high voltage (reference to V <sub>RL</sub> )                                       | V <sub>RH</sub>                      | -0.3                                | 5.5                                  | V    |
| 14   | V <sub>SS</sub> to V <sub>SSA</sub> differential voltage  | V <sub>SS</sub> – V <sub>SSA</sub>   | -0.1                                | 0.1                                  | V    |
| 15   | V <sub>DD</sub> to V <sub>DDA</sub> differential voltage  | $V_{DD} - V_{DDA}$                   | -V <sub>DDA</sub>                   | $V_{DD}$                             | V    |
| 16   | V <sub>REF</sub> differential voltage   | $V_{RH} - V_{RL}$                    | -0.3                                | 5.5                                  | V    |
| 17   | $V_{RH}$ to $V_{DDA}$ differential voltage  | $V_{RH} - V_{DDA}$                   | -5.5                                | 5.5                                  | V    |
| 18   | V <sub>RL</sub> to V <sub>SSA</sub> differential voltage  | V <sub>RL</sub> – V <sub>SSA</sub>   | -0.3                                | 0.3                                  | V    |
| 19   | V <sub>DDEH</sub> to V <sub>DDA</sub> differential voltage  | V <sub>DDEH</sub> – V <sub>DDA</sub> | -V <sub>DDA</sub>                   | $V_{DDEH}$                           | V    |
| 20   | V <sub>DDF</sub> to V <sub>DD</sub> differential voltage  | $V_{\rm DDF} - V_{\rm DD}$           | -0.3                                | 0.3                                  | V    |
| 21   | $V_{RC33}$ to $V_{DDSYN}$ differential voltage spec has been moved to                               | Table 9 DC Electric                  | al Specification                    | ns, Spec 43a.                        |      |
| 22   | V <sub>SSSYN</sub> to V <sub>SS</sub> differential voltage  | V <sub>SSSYN</sub> – V <sub>SS</sub> | -0.1                                | 0.1                                  | V    |
| 23   | V <sub>RCVSS</sub> to V <sub>SS</sub> differential voltage  | V <sub>RCVSS</sub> – V <sub>SS</sub> | -0.1                                | 0.1                                  | V    |
| 24   | Maximum DC digital input current <sup>8</sup> (per pin, applies to all digital pins) <sup>4</sup>   | I <sub>MAXD</sub>                    | -2                                  | 2                                    | mA   |
| 25   | Maximum DC analog input current <sup>9</sup> (per pin, applies to all analog pins)                  | I <sub>MAXA</sub>                    | -3                                  | 3                                    | mA   |
| 26   | Maximum operating temperature range <sup>10</sup> Die junction temperature                          | ТЈ                                   | T <sub>L</sub>                      | 150.0                                | °C   |
| 27   | Storage temperature range   | T <sub>STG</sub>                     | -55.0                               | 150.0                                | °C   |

| Table 2. Absolute | Maximum | Ratings 1 | 1 | (continued) |
|-------------------|---------|-----------|---|-------------|
|-------------------|---------|-----------|---|-------------|

| Spec | Characteristic   | Symbol           | Min. | Max.           | Unit |
|------|--|------------------|------|----------------|------|
| 28   | Maximum solder temperature <sup>11</sup> Lead free (Pb-free) Leaded (SnPb) | T <sub>SDR</sub> |      | 260.0<br>245.0 | °C   |
| 29   | Moisture sensitivity level <sup>12</sup>                                   | MSL              | _    | 3              |      |

Functional operating conditions are given in the DC electrical specifications. Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond any of the listed maxima can affect device reliability or cause permanent damage to the device.

- $^2$  1.5 V  $\pm$  10% for proper operation. This parameter is specified at a maximum junction temperature of 150 °C.
- <sup>3</sup> All functional non-supply I/O pins are clamped to V<sub>SS</sub> and V<sub>DDE</sub>, or V<sub>DDEH</sub>.
- <sup>4</sup> AC signal overshoot and undershoot of up to ± 2.0 V of the input voltages is permitted for an accumulative duration of 60 hours over the complete lifetime of the device (injection current not limited for this duration).
- <sup>5</sup> Internal structures hold the voltage greater than −1.0 V if the injection current limit of 2 mA is met. Keep the negative DC voltage greater than −0.6 V on SINB during the internal power-on reset (POR) state.
- Internal structures hold the input voltage less than the maximum voltage on all pads powered by V<sub>DDEH</sub> supplies, if the maximum injection current specification is met (2 mA for all pins) and V<sub>DDEH</sub> is within the operating voltage specifications.
- Internal structures hold the input voltage less than the maximum voltage on all pads powered by V<sub>DDE</sub> supplies, if the maximum injection current specification is met (2 mA for all pins) and V<sub>DDE</sub> is within the operating voltage specifications.
- <sup>8</sup> Total injection current for all pins (including both digital and analog) must not exceed 25 mA.
- <sup>9</sup> Total injection current for all analog input pins must not exceed 15 mA.
- <sup>10</sup> Lifetime operation at these specification limits is not guaranteed.
- <sup>11</sup> Moisture sensitivity profile per IPC/JEDEC J-STD-020D.
- <sup>12</sup> Moisture sensitivity per JEDEC test method A112.

#### 3.2 Thermal Characteristics

The shaded rows in the following table indicate information specific to a four-layer board.

Table 3. MPC5534 Thermal Characteristic

|      |  |                  | Pack          |             |      |
|------|--|------------------|---------------|-------------|------|
| Spec | MPC5534 Thermal Characteristic   | Symbol           | 208<br>MAPBGA | 324<br>PBGA | Unit |
| 1    | Junction to ambient <sup>1, 2</sup> , natural convection (one-layer board)       | $R_{\theta JA}$  | 42            | 34          | °C/W |
| 2    | Junction to ambient <sup>1, 3</sup> , natural convection (four-layer board 2s2p) | $R_{\theta JA}$  | 26            | 23          | °C/W |
| 3    | Junction to ambient (@200 ft./min., one-layer board)                             | $R_{\theta JMA}$ | 34            | 28          | °C/W |
| 4    | Junction to ambient (@200 ft./min., four-layer board 2s2p)                       | $R_{\theta JMA}$ | 22            | 20          | °C/W |
| 5    | Junction to board <sup>4</sup> (four-layer board 2s2p)                           | $R_{\theta JB}$  | 15            | 15          | °C/W |
| 6    | Junction to case <sup>5</sup>  | $R_{\theta JC}$  | 8             | 10          | °C/W |
| 7    | Junction to package top <sup>6</sup> , natural convection                        | $\Psi_{JT}$      | 2             | 2           | °C/W |

Junction temperature is a function of: on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other board components, and board thermal resistance.

MPC5534 Microcontroller Data Sheet, Rev. 5

<sup>&</sup>lt;sup>2</sup> Per SEMI G38-87 and JEDEC JESD51-2 with the single-layer board in a horizontal position.

<sup>&</sup>lt;sup>3</sup> Per JEDEC JESD51-6 with the board in a horizontal position.

Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.

<sup>&</sup>lt;sup>5</sup> Indicates the average thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the cold plate temperature used for the case temperature.

# 3.2.1 General Notes for Specifications at Maximum Junction Temperature

An estimation of the device junction temperature, T<sub>1</sub>, can be obtained from the equation:

$$T_{J} = T_{A} + (R_{\theta JA} \times P_{D})$$

where:

 $T_A$  = ambient temperature for the package ( ${}^{o}C$ )

 $R_{\theta IA}$  = junction to ambient thermal resistance ( ${}^{\circ}C/W$ )

 $P_D$  = power dissipation in the package (W)

The thermal resistance values used are based on the JEDEC JESD51 series of standards to provide consistent values for estimations and comparisons. The difference between the values determined for the single-layer (1s) board compared to a four-layer board that has two signal layers, a power and a ground plane (2s2p), demonstrate that the effective thermal resistance is not a constant. The thermal resistance depends on the:

- Construction of the application board (number of planes)
- Effective size of the board which cools the component
- Quality of the thermal and electrical connections to the planes
- Power dissipated by adjacent components

Connect all the ground and power balls to the respective planes with one via per ball. Using fewer vias to connect the package to the planes reduces the thermal performance. Thinner planes also reduce the thermal performance. When the clearance between the vias leave the planes virtually disconnected, the thermal performance is also greatly reduced.

As a general rule, the value obtained on a single-layer board is within the normal range for the tightly packed printed circuit board. The value obtained on a board with the internal planes is usually within the normal range if the application board has:

- One oz. (35 micron nominal thickness) internal planes
- Components are well separated
- Overall power dissipation on the board is less than 0.02 W/cm<sup>2</sup>

The thermal performance of any component depends on the power dissipation of the surrounding components. In addition, the ambient temperature varies widely within the application. For many natural convection and especially closed box applications, the board temperature at the perimeter (edge) of the package is approximately the same as the local air temperature near the device. Specifying the local ambient conditions explicitly as the board temperature provides a more precise description of the local ambient conditions that determine the temperature of the device.

<sup>&</sup>lt;sup>6</sup> The thermal characterization parameter indicates the temperature difference between the package top and the junction temperature per JEDEC JESD51-2.

At a known board temperature, the junction temperature is estimated using the following equation:

$$T_{J} = T_{B} + (R_{\theta JB} \times P_{D})$$
 where:

 $T_J$  = junction temperature ( $^{\circ}$ C)

 $T_B$  = board temperature at the package perimeter ( ${}^{o}C/W$ )

 $R_{\theta JB}$  = junction-to-board thermal resistance (°C/W) per JESD51-8

 $P_D$  = power dissipation in the package (W)

When the heat loss from the package case to the air does not factor into the calculation, an acceptable value for the junction temperature is predictable. Ensure the application board is similar to the thermal test condition, with the component soldered to a board with internal planes.

The thermal resistance is expressed as the sum of a junction-to-case thermal resistance plus a case-to-ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$
 where:

 $R_{\theta JA}$  = junction-to-ambient thermal resistance ( ${}^{\circ}C/W$ )

 $R_{\rm HIC}$  = junction-to-case thermal resistance ( ${}^{\rm o}{\rm C/W}$ )

 $R_{\theta CA}$  = case-to-ambient thermal resistance ( ${}^{\circ}C/W$ )

 $R_{\theta JC}$  is device related and is not affected by other factors. The thermal environment can be controlled to change the case-to-ambient thermal resistance,  $R_{\theta CA}$ . For example, change the air flow around the device, add a heat sink, change the mounting arrangement on the printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device. This description is most useful for packages with heat sinks where 90% of the heat flow is through the case to heat sink to ambient. For most packages, a better model is required.

A more accurate two-resistor thermal model can be constructed from the junction-to-board thermal resistance and the junction-to-case thermal resistance. The junction-to-case thermal resistance describes when using a heat sink or where a substantial amount of heat is dissipated from the top of the package. The junction-to-board thermal resistance describes the thermal performance when most of the heat is conducted to the printed circuit board. This model can be used to generate simple estimations and for computational fluid dynamics (CFD) thermal models.

To determine the junction temperature of the device in the application on a prototype board, use the thermal characterization parameter ( $\Psi_{JT}$ ) to determine the junction temperature by measuring the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

 $T_T$  = thermocouple temperature on top of the package ( $^{o}$ C)

 $\Psi_{JT}$  = thermal characterization parameter ( ${}^{o}C/W$ )

 $P_D$  = power dissipation in the package (W)

MPC5534 Microcontroller Data Sheet, Rev. 5

The thermal characterization parameter is measured in compliance with the JESD51-2 specification using a 40-gauge type T thermocouple epoxied to the top center of the package case. Position the thermocouple so that the thermocouple junction rests on the package. Place a small amount of epoxy on the thermocouple junction and approximately 1 mm of wire extending from the junction. Place the thermocouple wire flat against the package case to avoid measurement errors caused by the cooling effects of the thermocouple wire.

#### References:

Semiconductor Equipment and Materials International 3081 Zanker Rd.
San Jose, CA., 95134
(408) 943-6900

MIL-SPEC and EIA/JESD (JEDEC) specifications are available from Global Engineering Documents at 800-854-7179 or 303-397-7956.

JEDEC specifications are available on the web at http://www.jedec.org.

- 1. C.E. Triplett and B. Joiner, "An Experimental Characterization of a 272 PBGA Within an Automotive Engine Controller Module," Proceedings of SemiTherm, San Diego, 1998, pp. 47–54.
- 2. G. Kromann, S. Shidore, and S. Addison, "Thermal Modeling of a PBGA for Air-Cooled Applications," Electronic Packaging and Production, pp. 53–58, March 1998.
- 3. B. Joiner and V. Adams, "Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling," Proceedings of SemiTherm, San Diego, 1999, pp. 212–220.

# 3.3 Package

The MPC5534 is available in packaged form. Read the package options in Section 2, "Ordering Information." Refer to Section 4, "Mechanicals," for pinouts and package drawings.

# 3.4 EMI (Electromagnetic Interference) Characteristics

Table 4. EMI Testing Specifications <sup>1</sup>

| Spec | Characteristic  | Minimum | Typical | Maximum                            | Unit |
|------|---|---------|---------|------------------------------------|------|
| 1    | Scan range  | 0.15    | _       | 1000                               | MHz  |
| 2    | Operating frequency   | _       | _       | f <sub>MAX</sub>                   | MHz  |
| 3    | V <sub>DD</sub> operating voltages  | _       | 1.5     | _                                  | V    |
| 4    | V <sub>DDSYN</sub> , V <sub>RC33</sub> , V <sub>DD33</sub> , V <sub>FLASH</sub> , V <sub>DDE</sub> operating voltages | _       | 3.3     | _                                  | V    |
| 5    | V <sub>PP</sub> V <sub>DDEH</sub> , V <sub>DDA</sub> operating voltages   | _       | 5.0     | _                                  | V    |
| 6    | Maximum amplitude   | _       | _       | 14 <sup>2</sup><br>32 <sup>3</sup> | dBuV |
| 7    | Operating temperature   | _       | _       | 25                                 | °C   |

EMI testing and I/O port waveforms per SAE J1752/3 issued 1995-03. Qualification testing was performed on the MPC5554 and applied to the MPC5500 family as generic EMI performance data.

<sup>&</sup>lt;sup>2</sup> Measured with the single-chip EMI program.

<sup>&</sup>lt;sup>3</sup> Measured with the expanded EMI program.

# 3.5 ESD (Electromagnetic Static Discharge) Characteristics

Table 5. ESD Ratings 1, 2

| Characteristic                            | Symbol   | Value             | Unit   |
|---|----------|-------------------|--------|
| ESD for human body model (HBM)            |          | 2000              | V      |
| LIDM sireuit description                  | R1       | 1500              | Ω      |
| HBM circuit description                   | С        | 100               | pF     |
| ESD for field induced charge model (EDCM) |          | 500 (all pins)    |        |
| ESD for field induced charge model (FDCM) |          | 750 (corner pins) | V      |
| Number of pulses per pin:                 |          |                   |        |
| Positive pulses (HBM)                     | _        | 1                 | _      |
| Negative pulses (HBM)                     | <u> </u> | 1                 | _      |
| Interval of pulses                        | _        | 1                 | second |

All ESD testing conforms to CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.

# 3.6 Voltage Regulator Controller (V<sub>RC</sub>) and Power-On Reset (POR) Electrical Specifications

The following table lists the V<sub>RC</sub> and POR electrical specifications:

Table 6. V<sub>RC</sub> and POR Electrical Specifications

| Spec | Charac   | teristic  | Symbol                   | Min.                     | Max.                         | Units |
|------|--|---|--------------------------|--------------------------|------------------------------|-------|
| 1    | 1.5 V (V <sub>DD</sub> ) POR <sup>1</sup>  | Negated (ramp up)<br>Asserted (ramp down)   | V <sub>POR15</sub>       | 1.1<br>1.1               | 1.35<br>1.35                 | V     |
| 2    | 3.3 V (V <sub>DDSYN</sub> ) POR <sup>1</sup>   | Asserted (ramp up) Negated (ramp up) Asserted (ramp down) Negated (ramp down)   | V <sub>POR33</sub>       | 0.0<br>2.0<br>2.0<br>0.0 | 0.30<br>2.85<br>2.85<br>0.30 | V     |
| 3    | RESET pin supply (V <sub>DDEH6</sub> ) POR <sup>1, 2</sup>   | Negated (ramp up)<br>Asserted (ramp down)   | V <sub>POR5</sub>        | 2.0<br>2.0               | 2.85<br>2.85                 | V     |
| 4    |  | Before V <sub>RC</sub> allows the pass transistor to start turning on   | V <sub>TRANS_START</sub> | 1.0                      | 2.0                          | V     |
| 5    | V <sub>RC33</sub> voltage  | When V <sub>RC</sub> allows the pass transistor to completely turn on <sup>3, 4</sup>                                   | V <sub>TRANS_ON</sub>    | 2.0                      | 2.85                         | V     |
| 6    |  | When the voltage is greater than the voltage at which the $V_{RC}$ keeps the 1.5 V supply in regulation <sup>5, 6</sup> | V <sub>VRC33REG</sub>    | 3.0                      | _                            | V     |
|      | Current can be sourced   | -40° C  |                          | 11.0                     | _                            | mA    |
| 7    | by V <sub>RCCTL</sub> at Tj:   | 25° C   | I <sub>VRCCTL</sub> 7    | 9.0                      | _                            | mA    |
|      |  | 150° C  |                          | 7.5                      | _                            | mA    |
| 8    | Voltage differential during power up s $V_{DD33}$ can lag $V_{DDSYN}$ or $V_{DDEH6}$ bel $V_{POR33}$ and $V_{POR5}$ minimums respectively. | V <sub>DD33_LAG</sub>   | _                        | 1.0                      | V                            |       |

MPC5534 Microcontroller Data Sheet, Rev. 5

Device failure is defined as: 'If after exposure to ESD pulses, the device does not meet the device specification requirements, which includes the complete DC parametric and functional testing at room temperature and hot temperature.

Table 6. V<sub>RC</sub> and POR Electrical Specifications (continued)

| Spec | Charact  | Symbol           | Min.               | Max.     | Units |   |
|------|--|------------------|--------------------|----------|-------|---|
| 9    | Absolute value of slew rate on power   | _                | _                  | 50       | V/ms  |   |
|      | Required gain at Tj:<br>I <sub>DD</sub> ÷ I <sub>VRCCTL</sub> (@ f <sub>sys</sub> = f <sub>MAX</sub> ) | – 40° C<br>25° C | BETA <sup>10</sup> | 35<br>40 |       | _ |
|      | 6, 7, 8, 9   | 150° C           |                    | 50       | 500   | _ |

The internal POR signals are V<sub>POR15</sub>, V<sub>POR33</sub>, and V<sub>POR5</sub>. On power up, assert RESET before the internal POR negates. RESET must remain asserted until the power supplies are within the operating conditions as specified in Table 9 DC Electrical Specifications. On power down, assert RESET before any power supplies fall outside the operating conditions and until the internal POR asserts.

- $^{2}$  V<sub>IL S</sub> (Table 9, Spec15) is guaranteed to scale with V<sub>DDEH6</sub> down to V<sub>POR5</sub>.
- Supply full operating current for the 1.5 V supply when the 3.3 V supply reaches this range.
- 4 It is possible to reach the current limit during ramp up—do not treat this event as short circuit current.
- <sup>5</sup> At peak current for device.
- Requires compliance with Freescale's recommended board requirements and transistor recommendations. Board signal traces/routing from the  $V_{RCCTL}$  package signal to the base of the external pass transistor and between the emitter of the pass transistor to the  $V_{DD}$  package signals must have a maximum of 100 nH inductance and minimal resistance (less than 1  $\Omega$ ).  $V_{RCCTL}$  must have a nominal 1  $\mu$ F phase compensation capacitor to ground.  $V_{DD}$  must have a 20  $\mu$ F (nominal) bulk capacitor (greater than 4  $\mu$ F over all conditions, including lifetime). Place high-frequency bypass capacitors consisting of eight 0.01  $\mu$ F, two 0.1  $\mu$ F, and one 1  $\mu$ F capacitors around the package on the  $V_{DD}$  supply signals.
- $^{7}$  I<sub>VRCCTL</sub> is measured at the following conditions: V<sub>DD</sub> = 1.35 V, V<sub>RC33</sub> = 3.1 V, V<sub>VRCCTL</sub> = 2.2 V.
- Refer to Table 1 for the maximum operating frequency.
- <sup>9</sup> Values are based on I<sub>DD</sub> from high-use applications as explained in the I<sub>DD</sub> Electrical Specification.
- $^{10}$  BETA represents the worst-case external transistor. It is measured on a per-part basis and calculated as ( $I_{DD} \div I_{VRCCTL}$ ).

# 3.7 Power-Up/Down Sequencing

Power sequencing between the 1.5 V power supply and  $V_{DDSYN}$  or the  $\overline{RESET}$  power supplies is required if using an external 1.5 V power supply with  $V_{RC33}$  tied to ground (GND). To avoid power-sequencing,  $V_{RC33}$  must be powered up within the specified operating range, even if the on-chip voltage regulator controller is not used. Refer to Section 3.7.2, "Power-Up Sequence (VRC33 Grounded)," and Section 3.7.3, "Power-Down Sequence (VRC33 Grounded)."

Power sequencing requires that  $V_{DD33}$  must reach a certain voltage where the values are read as ones before the POR signal negates. Refer to Section 3.7.1, "Input Value of Pins During POR Dependent on VDD33."

Although power sequencing is not required between  $V_{RC33}$  and  $V_{DDSYN}$  during power up,  $V_{RC33}$  must not lead  $V_{DDSYN}$  by more than 600 mV or lag by more than 100 mV for the  $V_{RC}$  stage turn-on to operate within specification. Higher spikes in the emitter current of the pass transistor occur if  $V_{RC33}$  leads or lags  $V_{DDSYN}$  by more than these amounts. The value of that higher spike in current depends on the board power supply circuitry and the amount of board level capacitance.

Furthermore, when all of the PORs negate, the system clock starts to toggle, adding another large increase of the current consumed by  $V_{RC33}$ . If  $V_{RC33}$  lags  $V_{DDSYN}$  by more than 100 mV, the increase in current consumed can drop  $V_{DD}$  low enough to assert the 1.5 V POR again. Oscillations are possible when the 1.5 V POR asserts and stops the system clock, causing the voltage on  $V_{DD}$  to rise until the 1.5 V POR negates again. All oscillations stop when  $V_{RC33}$  is powered sufficiently.

When powering down,  $V_{RC33}$  and  $V_{DDSYN}$  have no delta requirement to each other, because the bypass capacitors internal and external to the device are already charged. When not powering up or down, no delta between  $V_{RC33}$  and  $V_{DDSYN}$  is required for the  $V_{RC}$  to operate within specification.

There are no power up/down sequencing requirements to prevent issues such as latch-up, excessive current spikes, and so on. Therefore, the state of the I/O pins during power up and power down varies depending on which supplies are powered.

Table 7 gives the pin state for the sequence cases for all pins with pad type pad\_fc (fast type).

| V <sub>DDE</sub> | V <sub>DD33</sub> | V <sub>DD</sub> | POR      | Pin Status for Fast Pad Output Driver pad_fc (fast) |
|------------------|-------------------|-----------------|----------|---|
| Low              | _                 | _               | Asserted | Low   |
| $V_{DDE}$        | Low               | Low             | Asserted | High  |
| $V_{DDE}$        | Low               | V <sub>DD</sub> | Asserted | High  |
| $V_{DDE}$        | V <sub>DD33</sub> | Low             | Asserted | High impedance (Hi-Z)                               |
| $V_{DDE}$        | V <sub>DD33</sub> | V <sub>DD</sub> | Asserted | Hi-Z  |
| $V_{DDE}$        | V <sub>DD33</sub> | V <sub>DD</sub> | Negated  | Functional  |

Table 7. Pin Status for Fast Pads During the Power Sequence

Table 8 gives the pin state for the sequence cases for all pins with pad type pad\_mh (medium type) and pad\_sh (slow type).

| V <sub>DDEH</sub> | V <sub>DD</sub> | POR      | Pin Status for Medium and Slow Pad Output Driver pad_mh (medium) pad_sh (slow) |
|-------------------|-----------------|----------|--|
| Low               | _               | Asserted | Low  |
| V <sub>DDEH</sub> | Low             | Asserted | High impedance (Hi-Z)  |
| $V_{DDEH}$        | $V_{DD}$        | Asserted | Hi-Z   |
| V <sub>DDEH</sub> | V <sub>DD</sub> | Negated  | Functional   |

Table 8. Pin Status for Medium and Slow Pads During the Power Sequence

The values in Table 7 and Table 8 do not include the effect of the weak-pull devices on the output pins during power up.

Before exiting the internal POR state, the pins go to a high-impedance state until POR negates. When the internal POR negates, the functional state of the signal during reset applies and the weak-pull devices (up or down) are enabled as defined in the device reference manual. If  $V_{DD}$  is too low to correctly propagate the logic signals, the weak-pull devices can pull the signals to  $V_{DDE}$  and  $V_{DDEH}$ .

To avoid this condition, minimize the ramp time of the  $V_{DD}$  supply to a time period less than the time required to enable the external circuitry connected to the device outputs.

# 3.7.1 Input Value of Pins During POR Dependent on V<sub>DD33</sub>

When powering up the device,  $V_{DD33}$  must not lag the latest  $V_{DDSYN}$  or  $\overline{RESET}$  power pin ( $V_{DDEH6}$ ) by more than the  $V_{DD33}$  lag specification listed in Table 6, spec 8. This avoids accidentally selecting the bypass clock mode because the internal versions of PLLCFG[0:1] and  $\overline{RSTCFG}$  are not powered and therefore cannot read the default state when POR negates.  $V_{DD33}$  can lag  $V_{DDSYN}$  or the  $\overline{RESET}$  power pin ( $V_{DDEH6}$ ), but cannot lag both by more than the  $V_{DD33}$  lag specification. This  $V_{DD33}$  lag specification applies during power up only.  $V_{DD33}$  has no lead or lag requirements when powering down.

# 3.7.2 Power-Up Sequence (V<sub>RC33</sub> Grounded)

The 1.5 V  $V_{DD}$  power supply must rise to 1.35 V before the 3.3 V  $V_{DDSYN}$  power supply and the  $\overline{RESET}$  power supply rises above 2.0 V. This ensures that digital logic in the PLL for the 1.5 V power supply does not begin to operate below the specified operation range lower limit of 1.35 V. Because the internal 1.5 V POR is disabled, the internal 3.3 V POR or the  $\overline{RESET}$  power POR must hold the device in reset. Since they can negate as low as 2.0 V,  $V_{DD}$  must be within specification before the 3.3 V POR and the  $\overline{RESET}$  POR negate.

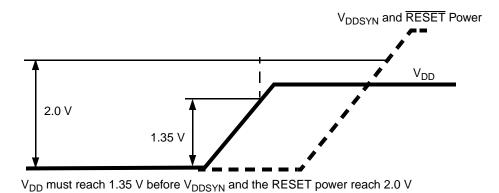


Figure 2. Power-Up Sequence (V<sub>RC33</sub> Grounded)

#### 3.7.3 Power-Down Sequence (V<sub>RC33</sub> Grounded)

The only requirement for the power-down sequence with  $V_{RC33}$  grounded is if  $V_{DD}$  decreases to less than its operating range,  $V_{DDSYN}$  or the  $\overline{RESET}$  power must decrease to less than 2.0 V before the  $V_{DD}$  power increases to its operating range. This ensures that the digital 1.5 V logic, which is reset only by an ORed POR and can cause the 1.5 V supply to decrease less than its specification value, resets correctly. See Table 6, footnote 1.

MPC5534 Microcontroller Data Sheet, Rev. 5

# 3.8 DC Electrical Specifications

Table 9. DC Electrical Specifications ( $T_A = T_L \text{ to } T_H$ )

| Spec | Characteristic   | Symbol             | Min  | Max.   | Unit                 |
|------|--|--------------------|--|--|----------------------|
| 1    | Core supply voltage (average DC RMS voltage)   | V <sub>DD</sub>    | 1.35   | 1.65   | V                    |
| 2    | Input/output supply voltage (fast input/output) 1  | V <sub>DDE</sub>   | 1.62   | 3.6  | V                    |
| 3    | Input/output supply voltage (slow and medium input/output)   | V <sub>DDEH</sub>  | 3.0  | 5.25   | V                    |
| 4    | 3.3 V input/output buffer voltage  | V <sub>DD33</sub>  | 3.0  | 3.6  | V                    |
| 5    | Voltage regulator control input voltage  | V <sub>RC33</sub>  | 3.0  | 3.6  | V                    |
| 6    | Analog supply voltage <sup>2</sup>   | V <sub>DDA</sub>   | 4.5  | 5.25   | V                    |
| 8    | Flash programming voltage <sup>3</sup>   | V <sub>PP</sub>    | 4.5  | 5.25   | V                    |
| 9    | Flash read voltage   | V <sub>FLASH</sub> | 3.0  | 3.6  | V                    |
| 10   | SRAM standby voltage <sup>4</sup>  | V <sub>STBY</sub>  | 0.8  | 1.2  | V                    |
| 11   | Clock synthesizer operating voltage  | V <sub>DDSYN</sub> | 3.0  | 3.6  | V                    |
| 12   | Fast I/O input high voltage  | V <sub>IH_F</sub>  | $0.65 \times V_{DDE}$                            | V <sub>DDE</sub> + 0.3                           | V                    |
| 13   | Fast I/O input low voltage   | V <sub>IL_F</sub>  | V <sub>SS</sub> - 0.3                            | $0.35 \times V_{DDE}$                            | V                    |
| 14   | Medium and slow I/O input high voltage   | V <sub>IH_S</sub>  | $0.65 \times V_{DDEH}$                           | V <sub>DDEH</sub> + 0.3                          | V                    |
| 15   | Medium and slow I/O input low voltage  | V <sub>IL_S</sub>  | V <sub>SS</sub> - 0.3                            | $0.35 \times V_{DDEH}$                           | V                    |
| 16   | Fast input hysteresis  | V <sub>HYS_F</sub> | 0.1 × V <sub>DDE</sub>                           |  | V                    |
| 17   | Medium and slow I/O input hysteresis   | V <sub>HYS_S</sub> | 0.1 × V <sub>DDEH</sub>                          |  | V                    |
| 18   | Analog input voltage   | V <sub>INDC</sub>  | V <sub>SSA</sub> - 0.3                           | V <sub>DDA</sub> + 0.3                           | V                    |
| 19   | Fast output high voltage (I <sub>OH_F</sub> = −2.0 mA)   | V <sub>OH_F</sub>  | $0.8 \times V_{DDE}$                             | _  | V                    |
| 20   | Slow and medium output high voltage $I_{OH\_S} = -2.0 \text{ mA}$ $I_{OH\_S} = -1.0 \text{ mA}$                          | V <sub>OH_S</sub>  | $0.80 \times V_{DDEH}$<br>$0.85 \times V_{DDEH}$ | _  | V                    |
| 21   | Fast output low voltage (I <sub>OL_F</sub> = 2.0 mA)   | V <sub>OL_F</sub>  | _  | $0.2 \times V_{DDE}$                             | V                    |
| 22   | Slow and medium output low voltage  I <sub>OL_S</sub> = 2.0 mA I <sub>OL_S</sub> = 1.0 mA                                | V <sub>OL_S</sub>  | _  | $0.20 \times V_{DDEH}$<br>$0.15 \times V_{DDEH}$ | V                    |
| 23   | Load capacitance (fast I/O) <sup>5</sup> DSC (SIU_PCR[8:9]) = 0b00 = 0b01 = 0b10 = 0b11                                  | C <sub>L</sub>     | _<br>_<br>_<br>_                                 | 10<br>20<br>30<br>50                             | pF<br>pF<br>pF<br>pF |
| 24   | Input capacitance (digital pins)   | C <sub>IN</sub>    | _  | 7  | pF                   |
| 25   | Input capacitance (analog pins)  | C <sub>IN_A</sub>  | _  | 10   | pF                   |
| 26   | Input capacitance: (Shared digital and analog pins AN[12]_MA[0]_SDS, AN[13]_MA[1]_SDO, AN[14]_MA[2]_SDI, and AN[15]_FCK) | C <sub>IN_M</sub>  | _  | 12   | pF                   |

MPC5534 Microcontroller Data Sheet, Rev. 5

Table 9. DC Electrical Specifications ( $T_A = T_L \text{ to } T_H$ ) (continued)

| Spec | Characteristic  | Symbol   | Min                             | Max.  | Unit   |
|------|---|--|---------------------------------|---|--|
| 27a  | Operating current 1.5 V supplies @ 82 MHz: $^{6,7}$ V <sub>DD</sub> (including V <sub>DDF</sub> max current) @1.65 V high use $^{8,9,10,11,12}$ V <sub>DD</sub> (including V <sub>DDF</sub> max current) @1.35 V high use $^{8,9,10,11,12}$ | I <sub>DD</sub><br>I <sub>DD</sub>   |                                 | 250<br>180  | mA<br>mA                                     |
| 27b  | Operating current 1.5 V supplies @ 68 MHz: $^{13, 14}$ V <sub>DD</sub> (including V <sub>DDF</sub> max current) @1.65 V high use $^{15, 16, 17}$ V <sub>DD</sub> (including V <sub>DDF</sub> max current) @1.35 V high use $^{15, 16, 17}$  | I <sub>DD</sub><br>I <sub>DD</sub>   |                                 | 210<br>160  | mA<br>mA                                     |
| 27c  | Operating current 1.5 V supplies @ 42 MHz: $^{13, 14}$ V <sub>DD</sub> (including V <sub>DDF</sub> max current) @1.65 V high use $^{15, 16, 17}$ V <sub>DD</sub> (including V <sub>DDF</sub> max current) @1.35 V high use $^{15, 16, 17}$  | I <sub>DD</sub><br>I <sub>DD</sub>   | _<br>_                          | 130<br>110  | mA<br>mA                                     |
| 27d  | Refer to Figure 3 for an interpolation of this data. 18  IDD_STBY @ 25° C VSTBY @ 0.8 V VSTBY @ 1.0 V VSTBY @ 1.2 V   | I <sub>DD_STBY</sub><br>I <sub>DD_STBY</sub><br>I <sub>DD_STBY</sub>   | _<br>_<br>_                     | 20<br>30<br>50  | μΑ<br>μΑ<br>μΑ                               |
|      | I <sub>DD_STBY</sub> @ 60° C<br>V <sub>STBY</sub> @ 0.8 V<br>V <sub>STBY</sub> @ 1.0 V<br>V <sub>STBY</sub> @ 1.2 V   | I <sub>DD_STBY</sub><br>I <sub>DD_STBY</sub><br>I <sub>DD_STBY</sub>   | _<br>_<br>_                     | 70<br>100<br>200  | μΑ<br>μΑ<br>μΑ                               |
|      | I <sub>DD_STBY</sub> @ 150° C (Tj)<br>V <sub>STBY</sub> @ 0.8 V<br>V <sub>STBY</sub> @ 1.0 V<br>V <sub>STBY</sub> @ 1.2 V   | I <sub>DD_STBY</sub><br>I <sub>DD_STBY</sub><br>I <sub>DD_STBY</sub>   | _<br>_<br>_<br>_                | 1200<br>1500<br>2000  | μΑ<br>μΑ<br>μΑ                               |
| 28   | Operating current 3.3 V supplies @ f <sub>MAX</sub> MHz $V_{DD33}^{19}$   | I <sub>DD_33</sub>   | _                               | 2 + (values<br>derived from<br>procedure of<br>footnote <sup>19</sup> ) | mA   |
|      | V <sub>FLASH</sub>  | I <sub>VFLASH</sub>  | _                               | 10  | mA   |
|      | V <sub>DDSYN</sub>  | I <sub>DDSYN</sub>   | _                               | 15  | mA   |
| 29   | Operating current 5.0 V supplies (12 MHz ADCLK):  V <sub>DDA</sub> (V <sub>DDA0</sub> + V <sub>DDA1</sub> )  Analog reference supply current (V <sub>RH</sub> , V <sub>RL</sub> )  V <sub>PP</sub>  | I <sub>DD_A</sub><br>I <sub>REF</sub><br>I <sub>PP</sub>   | _<br>_<br>_<br>_                | 20.0<br>1.0<br>25.0   | mA<br>mA<br>mA                               |
| 30   | Operating current V <sub>DDE</sub> supplies: <sup>20</sup> V <sub>DDEH1</sub> V <sub>DDE2</sub> V <sub>DDE3</sub> V <sub>DDEH4</sub> V <sub>DDE5</sub> V <sub>DDEH6</sub> V <sub>DDE7</sub> V <sub>DDEH8</sub> V <sub>DDEH9</sub>           | I <sub>DD1</sub> I <sub>DD2</sub> I <sub>DD3</sub> I <sub>DD4</sub> I <sub>DD5</sub> I <sub>DD6</sub> I <sub>DD7</sub> I <sub>DD8</sub> I <sub>DD9</sub> | -<br>-<br>-<br>-<br>-<br>-<br>- | Refer to footnote <sup>20</sup>   | mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA<br>mA |

Table 9. DC Electrical Specifications ( $T_A = T_L \text{ to } T_H$ ) (continued)

| Spec | Characteristic  | Symbol                                 | Min                    | Max.                   | Unit           |
|------|---|--|------------------------|------------------------|----------------|
| 31   | Fast I/O weak pullup current <sup>21</sup> 1.62–1.98 V 2.25–2.75 V 3.00–3.60 V      |  | 10<br>20<br>20         | 110<br>130<br>170      | μΑ<br>μΑ<br>μΑ |
|      | Fast I/O weak pulldown current <sup>21</sup> 1.62–1.98 V 2.25–2.75 V 3.00–3.60 V    | - I <sub>ACT_F</sub>                   | 10<br>20<br>20         | 100<br>130<br>170      | μΑ<br>μΑ<br>μΑ |
| 32   | Slow and medium I/O weak pullup/down current <sup>21</sup> 3.0–3.6 V 4.5–5.5 V      | I <sub>ACT_S</sub>                     | 10<br>20               | 150<br>170             | μΑ<br>μΑ       |
| 33   | I/O input leakage current <sup>22</sup>   | I <sub>INACT_D</sub>                   | -2.5                   | 2.5                    | μА             |
| 34   | DC injection current (per pin)  | I <sub>IC</sub>                        | -2.0                   | 2.0                    | mA             |
| 35   | Analog input current, channel off <sup>23</sup>                                     | I <sub>INACT_A</sub>                   | -150                   | 150                    | nA             |
| 35a  | Analog input current, shared analog / digital pins (AN[12], AN[13], AN[14], AN[15]) | I <sub>INACT_AD</sub>                  | -2.5                   | 2.5                    | μА             |
| 36   | V <sub>SS</sub> to V <sub>SSA</sub> differential voltage <sup>24</sup>              | V <sub>SS</sub> - V <sub>SSA</sub>     | -100                   | 100                    | mV             |
| 37   | Analog reference low voltage  | $V_{RL}$                               | V <sub>SSA</sub> - 0.1 | V <sub>SSA</sub> + 0.1 | V              |
| 38   | V <sub>RL</sub> differential voltage  | V <sub>RL</sub> – V <sub>SSA</sub>     | -100                   | 100                    | mV             |
| 39   | Analog reference high voltage   | V <sub>RH</sub>                        | V <sub>DDA</sub> – 0.1 | V <sub>DDA</sub> + 0.1 | V              |
| 40   | V <sub>REF</sub> differential voltage   | $V_{RH} - V_{RL}$                      | 4.5                    | 5.25                   | V              |
| 41   | V <sub>SSSYN</sub> to V <sub>SS</sub> differential voltage                          | V <sub>SSSYN</sub> - V <sub>SS</sub>   | <b>-</b> 50            | 50                     | mV             |
| 42   | V <sub>RCVSS</sub> to V <sub>SS</sub> differential voltage                          | V <sub>RCVSS</sub> - V <sub>SS</sub>   | <b>-</b> 50            | 50                     | mV             |
| 43   | V <sub>DDF</sub> to V <sub>DD</sub> differential voltage                            | $V_{DDF} - V_{DD}$                     | -100                   | 100                    | mV             |
| 43a  | V <sub>RC33</sub> to V <sub>DDSYN</sub> differential voltage                        | V <sub>RC33</sub> – V <sub>DDSYN</sub> | -0.1                   | 0.1 <sup>25</sup>      | V              |
| 44   | Analog input differential signal range (with common mode 2.5 V)                     | V <sub>IDIFF</sub>                     | -2.5                   | 2.5                    | V              |
| 45   | Operating temperature range, ambient (packaged)                                     | $T_A = (T_L \text{ to } T_H)$          | T <sub>L</sub>         | T <sub>H</sub>         | οС             |
| 46   | Slew rate on power-supply pins  | _                                      | _                      | 50                     | V/ms           |

 $<sup>^{1}</sup>$  V<sub>DDE2</sub> and V<sub>DDE3</sub> are limited to 2.25–3.6 V only if SIU\_ECCR[EBTS] = 0; V<sub>DDE2</sub> and V<sub>DDE3</sub> have a range of 1.6–3.6 V if SIU\_ECCR[EBTS] = 1.

#### MPC5534 Microcontroller Data Sheet, Rev. 5

 $<sup>^{2}</sup>$  |  $V_{DDA0} - V_{DDA1}$  | must be < 0.1 V.

 $<sup>^{3}\,\,</sup>$  V<sub>PP</sub> can drop to 3.0 V during read operations.

<sup>&</sup>lt;sup>4</sup> If standby operation is not required, connect V<sub>STBY</sub> to ground.

<sup>&</sup>lt;sup>5</sup> Applies to CLKOUT, external bus pins, and Nexus pins.

<sup>&</sup>lt;sup>6</sup> Maximum average RMS DC current.

 $<sup>^7</sup>$  Figure 3 shows an illustration of the  $I_{\mbox{\scriptsize DD\_STBY}}$  values interpolated for these temperature values.

<sup>&</sup>lt;sup>8</sup> Average current measured on Automotive benchmark.

<sup>&</sup>lt;sup>9</sup> Peak currents can be higher on specialized code.

<sup>&</sup>lt;sup>10</sup> High use current measured while running optimized SPE assembly code with all channels of the eMIOS and eTPU running autonomously, plus the eDMA transferring data continuously from SRAM to SRAM.

- <sup>11</sup> Power requirements for the V<sub>DD33</sub> supply depend on the frequency of operation, load of all I/O pins, and the voltages on the I/O segments. Refer to Table 11 for values to calculate power dissipation for specific operation.
- <sup>12</sup> Power requirements for each I/O segment are dependent on the frequency of operation and load of the I/O pins on a particular I/O segment, and the voltage of the I/O segment. Refer to Table 10 for values to calculate power dissipation for specific operation. The total power consumption of an I/O segment is the sum of the individual power consumptions for each pin on the segment.
- <sup>13</sup> Maximum average RMS DC current.
- <sup>14</sup> Figure 3 shows an illustration of the I<sub>DD\_STBY</sub> values interpolated for these temperature values.
- <sup>15</sup> Average current measured on automotive benchmark.
- <sup>16</sup> Peak currents can be higher on specialized code.
- <sup>17</sup> High use current measured while running optimized SPE assembly code with all channels of the eMIOS and eTPU running autonomously, plus the eDMA transferring data continuously from SRAM to SRAM.
- $^{18}$  Figure 3 shows an illustration of the  $I_{DD\ STBY}$  values interpolated for these temperature values.
- <sup>19</sup> Power requirements for the V<sub>DD33</sub> supply depend on the frequency of operation, load of all I/O pins, and the voltages on the I/O segments. Refer to Table 11 for values to calculate the power dissipation for a specific operation.
- <sup>20</sup> Power requirements for each I/O segment are dependent on the frequency of operation and load of the I/O pins on a particular I/O segment, and the voltage of the I/O segment. Refer to Table 10 for values to calculate power dissipation for specific operation. The total power consumption of an I/O segment is the sum of the individual power consumptions for each pin on the segment.
- $^{21}$  Absolute value of current, measured at  $V_{IL}$  and  $V_{IH}$ .
- <sup>22</sup> Weak pullup/down inactive. Measured at V<sub>DDF</sub> = 3.6 V and V<sub>DDFH</sub> = 5.25 V. Applies to pad types: pad\_fc, pad\_sh, and pad\_mh.
- <sup>23</sup> Maximum leakage occurs at maximum operating temperature. Leakage current decreases by approximately one-half for each 8 °C to 12 °C, in the ambient temperature range of 50 °C to 125 °C. Applies to pad types: pad\_a and pad\_ae.
- $^{24}$  V\_{SSA} refers to both V\_{SSA0} and V\_SSA1. | V\_SSA0 V\_SSA1 | must be < 0.1 V.
- <sup>25</sup> Up to 0.6 V during power up and power down.

MPC5534 Microcontroller Data Sheet, Rev. 5

Freescale Semiconductor

16

Figure 3 shows an approximate interpolation of the  $I_{STBY}$  worst-case specification to estimate values at different voltages and temperatures. The vertical lines shown at 25 °C, 60 °C, and 150 °C in Figure 3 are the actual  $I_{DD\ STBY}$  specifications (27d) listed in Table 9.

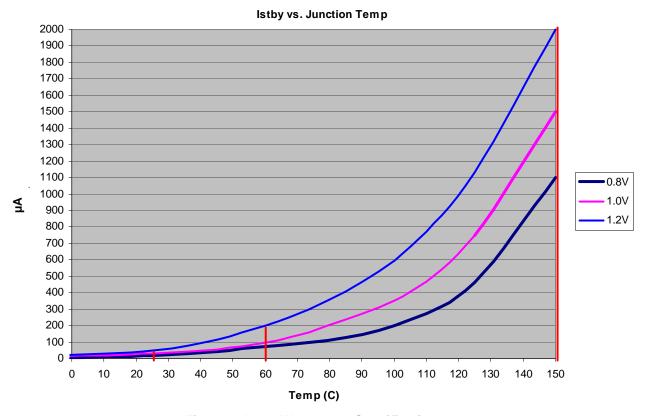


Figure 3. I<sub>STBY</sub> Worst-case Specifications

MPC5534 Microcontroller Data Sheet, Rev. 5

### 3.8.1 I/O Pad Current Specifications

The power consumption of an I/O segment depends on the usage of the pins on a particular segment. The power consumption is the sum of all output pin currents for a segment. The output pin current can be calculated from Table 10 based on the voltage, frequency, and load on the pin. Use linear scaling to calculate pin currents for voltage, frequency, and load parameters that fall outside the values given in Table 10.

Table 10. I/O Pad Average DC Current  $(T_A = T_L \text{ to } T_H)^1$ 

| Spec | Pad Type | Symbol              | Frequency<br>(MHz) | Load <sup>2</sup> (pF) | Voltage (V) | Drive Select /<br>Slew Rate<br>Control Setting | Current (mA) |
|------|----------|---------------------|--------------------|------------------------|-------------|--|--------------|
| 1    |          |                     | 25                 | 50                     | 5.25        | 11   | 8.0          |
| 2    | Slow     |                     | 10                 | 50                     | 5.25        | 01   | 3.2          |
| 3    | Slow     | I <sub>DRV_SH</sub> | 2                  | 50                     | 5.25        | 00   | 0.7          |
| 4    |          |                     | 2                  | 200                    | 5.25        | 00   | 2.4          |
| 5    |          |                     | 50                 | 50                     | 5.25        | 11   | 17.3         |
| 6    | Medium   |                     | 20                 | 50                     | 5.25        | 01   | 6.5          |
| 7    | Medium   | I <sub>DRV_MH</sub> | 3.33               | 50                     | 5.25        | 00   | 1.1          |
| 8    |          |                     | 3.33               | 200                    | 5.25        | 00   | 3.9          |
| 9    |          |                     | 66                 | 10                     | 3.6         | 00   | 2.8          |
| 10   |          |                     | 66                 | 20                     | 3.6         | 01   | 5.2          |
| 11   |          |                     | 66                 | 30                     | 3.6         | 10   | 8.5          |
| 12   |          |                     | 66                 | 50                     | 3.6         | 11   | 11.0         |
| 13   |          |                     | 66                 | 10                     | 1.98        | 00   | 1.6          |
| 14   |          |                     | 66                 | 20                     | 1.98        | 01   | 2.9          |
| 15   |          |                     | 66                 | 30                     | 1.98        | 10   | 4.2          |
| 16   |          |                     | 66                 | 50                     | 1.98        | 11   | 6.7          |
| 17   |          |                     | 56                 | 10                     | 3.6         | 00   | 2.4          |
| 18   |          |                     | 56                 | 20                     | 3.6         | 01   | 4.4          |
| 19   |          |                     | 56                 | 30                     | 3.6         | 10   | 7.2          |
| 20   | Foot     |                     | 56                 | 50                     | 3.6         | 11   | 9.3          |
| 21   | Fast     | I <sub>DRV_FC</sub> | 56                 | 10                     | 1.98        | 00   | 1.3          |
| 22   |          |                     | 56                 | 20                     | 1.98        | 01   | 2.5          |
| 23   |          |                     | 56                 | 30                     | 1.98        | 10   | 3.5          |
| 24   |          |                     | 56                 | 50                     | 1.98        | 11   | 5.7          |
| 25   |          |                     | 40                 | 10                     | 3.6         | 00   | 1.7          |
| 26   |          |                     | 40                 | 20                     | 3.6         | 01   | 3.1          |
| 27   |          |                     | 40                 | 30                     | 3.6         | 10   | 5.1          |
| 28   |          |                     | 40                 | 50                     | 3.6         | 11   | 6.6          |
| 29   |          |                     | 40                 | 10                     | 1.98        | 00   | 1.0          |
| 30   |          |                     | 40                 | 20                     | 1.98        | 01   | 1.8          |
| 31   |          |                     | 40                 | 30                     | 1.98        | 10   | 2.5          |
| 32   |          |                     | 40                 | 50                     | 1.98        | 11   | 4.0          |

<sup>1</sup> These values are estimates from simulation and are not tested. Currents apply to output pins only.

<sup>&</sup>lt;sup>2</sup> All loads are lumped.

# 3.8.2 I/O Pad V<sub>DD33</sub> Current Specifications

The power consumption of the  $V_{DD33}$  supply dependents on the usage of the pins on all I/O segments. The power consumption is the sum of all input and output pin  $V_{DD33}$  currents for all I/O segments. The output pin  $V_{DD33}$  current can be calculated from Table 11 based on the voltage, frequency, and load on all fast (pad\_fc) pins. The input pin  $V_{DD33}$  current can be calculated from Table 11 based on the voltage, frequency, and load on all pad\_sh and pad\_mh pins. Use linear scaling to calculate pin currents for voltage, frequency, and load parameters that fall outside the values given in Table 11.

Table 11.  $V_{DD33}$  Pad Average DC Current  $(T_A = T_L \text{ to } T_H)^{-1}$ 

| Spec | Pad Type | Symbol             | Frequency<br>(MHz) | Load <sup>2</sup><br>(pF) | V <sub>DD33</sub> (V) | V <sub>DDE</sub><br>(V) | Drive<br>Select | Current<br>(mA) |  |
|------|----------|--------------------|--------------------|---------------------------|-----------------------|-------------------------|-----------------|-----------------|--|
|      | Inputs   |                    |                    |                           |                       |                         |                 |                 |  |
| 1    | Slow     | I <sub>33_SH</sub> | 66                 | 0.5                       | 3.6                   | 5.5                     | NA              | 0.003           |  |
| 2    | Medium   | I <sub>33_MH</sub> | 66                 | 0.5                       | 3.6                   | 5.5                     | NA              | 0.003           |  |
|      |          |                    |                    | Output                    | s                     |                         |                 |                 |  |
| 3    |          |                    | 66                 | 10                        | 3.6                   | 3.6                     | 00              | 0.35            |  |
| 4    |          |                    | 66                 | 20                        | 3.6                   | 3.6                     | 01              | 0.53            |  |
| 5    |          |                    | 66                 | 30                        | 3.6                   | 3.6                     | 10              | 0.62            |  |
| 6    |          |                    | 66                 | 50                        | 3.6                   | 3.6                     | 11              | 0.79            |  |
| 7    |          |                    | 66                 | 10                        | 3.6                   | 1.98                    | 00              | 0.35            |  |
| 8    |          |                    | 66                 | 20                        | 3.6                   | 1.98                    | 01              | 0.44            |  |
| 9    |          |                    | 66                 | 30                        | 3.6                   | 1.98                    | 10              | 0.53            |  |
| 10   |          |                    | 66                 | 50                        | 3.6                   | 1.98                    | 11              | 0.70            |  |
| 11   |          |                    | 56                 | 10                        | 3.6                   | 3.6                     | 00              | 0.30            |  |
| 12   |          |                    | 56                 | 20                        | 3.6                   | 3.6                     | 01              | 0.45            |  |
| 13   |          |                    | 56                 | 30                        | 3.6                   | 3.6                     | 10              | 0.52            |  |
| 14   | Fast     |                    | 56                 | 50                        | 3.6                   | 3.6                     | 11              | 0.67            |  |
| 15   | Γάδι     | I <sub>33_FC</sub> | 56                 | 10                        | 3.6                   | 1.98                    | 00              | 0.30            |  |
| 16   |          |                    | 56                 | 20                        | 3.6                   | 1.98                    | 01              | 0.37            |  |
| 17   |          |                    | 56                 | 30                        | 3.6                   | 1.98                    | 10              | 0.45            |  |
| 18   |          |                    | 56                 | 50                        | 3.6                   | 1.98                    | 11              | 0.60            |  |
| 19   |          |                    | 40                 | 10                        | 3.6                   | 3.6                     | 00              | 0.21            |  |
| 20   |          |                    | 40                 | 20                        | 3.6                   | 3.6                     | 01              | 0.31            |  |
| 21   |          |                    | 40                 | 30                        | 3.6                   | 3.6                     | 10              | 0.37            |  |
| 22   |          | 40                 | 50                 | 3.6                       | 3.6                   | 11                      | 0.48            |                 |  |
| 23   |          |                    | 40                 | 10                        | 3.6                   | 1.98                    | 00              | 0.21            |  |
| 24   |          |                    | 40                 | 20                        | 3.6                   | 1.98                    | 01              | 0.27            |  |
| 25   |          |                    | 40                 | 30                        | 3.6                   | 1.98                    | 10              | 0.32            |  |
| 26   |          |                    | 40                 | 50                        | 3.6                   | 1.98                    | 11              | 0.42            |  |

These values are estimated from simulation and not tested. Currents apply to output pins for the fast pads only and to input pins for the slow and medium pads only.

<sup>&</sup>lt;sup>2</sup> All loads are lumped.

### 3.9 Oscillator and FMPLL Electrical Characteristics

#### **Table 12. FMPLL Electrical Specifications**

 $(V_{DDSYN} = 3.0-3.6 \text{ V}; V_{SS} = V_{SSSYN} = 0.0 \text{ V}; T_A = T_L \text{ to } T_H)$ 

| Spec | Characteristic  | Symbol   | Minimum                         | Maximum  | Unit               |
|------|---|--|---------------------------------|--|--------------------|
| 1    | PLL reference frequency range: <sup>1</sup> Crystal reference External reference Dual controller (1:1 mode) | f <sub>ref_crystal</sub><br>f <sub>ref_ext</sub><br>f <sub>ref_1:1</sub> | 8<br>8<br>24                    | 20<br>20<br>f <sub>sys</sub> ÷ 2   | MHz                |
| 2    | System frequency <sup>2</sup>   | f <sub>sys</sub>   | $f_{ICO(MIN)} \div 2^{RFD}$     | f <sub>MAX</sub> <sup>3</sup>  | MHz                |
| 3    | System clock period   | t <sub>CYC</sub>   | _                               | 1 ÷ f <sub>sys</sub>   | ns                 |
| 4    | Loss of reference frequency <sup>4</sup>  | f <sub>LOR</sub>   | 100                             | 1000   | kHz                |
| 5    | Self-clocked mode (SCM) frequency <sup>5</sup>  | f <sub>SCM</sub>   | 7.4                             | 17.5   | MHz                |
|      | EXTAL input high voltage crystal mode <sup>6</sup>  | V <sub>IHEXT</sub>   | V <sub>XTAL</sub> + 0.4 V       | _  | V                  |
| 6    | All other modes [dual controller (1:1), bypass, external reference]   | $V_{IHEXT}$  | (V <sub>DDE5</sub> ÷ 2) + 0.4 V | _  | V                  |
|      | EXTAL input low voltage crystal mode <sup>7</sup>   | V <sub>ILEXT</sub>   | _                               | V <sub>XTAL</sub> – 0.4 V  | V                  |
| 7    | All other modes [dual controller (1:1), bypass, external reference]   | V <sub>ILEXT</sub>   | _                               | (V <sub>DDE5</sub> ÷ 2) – 0.4 V  | V                  |
| 8    | XTAL current <sup>8</sup>   | I <sub>XTAL</sub>  | 0.8                             | 3  | mA                 |
| 9    | Total on-chip stray capacitance on XTAL   | C <sub>S_XTAL</sub>  | _                               | 1.5  | pF                 |
| 10   | Total on-chip stray capacitance on EXTAL  | C <sub>S_EXTAL</sub>   | _                               | 1.5  | pF                 |
| 11   | Crystal manufacturer's recommended capacitive load  | C <sub>L</sub>   | Refer to crystal specification  | Refer to crystal specification   | pF                 |
| 12   | Discrete load capacitance to connect to EXTAL   | C <sub>L_EXTAL</sub>   | _                               | (2 × C <sub>L</sub> ) – C <sub>S_EXTAL</sub><br>– C <sub>PCB_EXTAL</sub>           | pF                 |
| 13   | Discrete load capacitance to connect to XTAL  | C <sub>L_XTAL</sub>  | _                               | $ \begin{array}{c} (2 \times C_L) - C_{S\_XTAL} \\ - C_{PCB\_XTAL} \end{array}^9 $ | pF                 |
| 14   | PLL lock time <sup>10</sup>   | t <sub>lpll</sub>  | _                               | 750  | μS                 |
| 15   | Dual controller (1:1) clock skew (between CLKOUT and EXTAL) 11, 12  | t <sub>skew</sub>  | -2                              | 2  | ns                 |
| 16   | Duty cycle of reference   | t <sub>DC</sub>  | 40                              | 60   | %                  |
| 17   | Frequency unLOCK range  | f <sub>UL</sub>  | -4.0                            | 4.0  | % f <sub>SYS</sub> |
| 18   | Frequency LOCK range  | f <sub>LCK</sub>   | -2.0                            | 2.0  | % f <sub>SYS</sub> |

MPC5534 Microcontroller Data Sheet, Rev. 5

#### **Table 12. FMPLL Electrical Specifications (continued)**

 $(V_{DDSYN} = 3.0-3.6 \text{ V}; V_{SS} = V_{SSSYN} = 0.0 \text{ V}; T_A = T_L \text{ to } T_H)$ 

| Spec | Characteristic  | Symbol              | Minimum | Maximum          | Unit                     |
|------|---|---------------------|---------|------------------|--------------------------|
| 19   | CLKOUT period jitter, measured at f <sub>SYS</sub> max: <sup>13, 14</sup> Peak-to-peak jitter (clock edge to clock edge) Long term jitter (averaged over a 2 ms interval) | C <sub>JITTER</sub> |         | 5.0<br>0.01      | %<br>f <sub>CLKOUT</sub> |
| 20   | Frequency modulation range limit <sup>15</sup> (do not exceed f <sub>sys</sub> maximum)   | C <sub>MOD</sub>    | 0.8     | 2.4              | %f <sub>SYS</sub>        |
| 21   | ICO frequency   $f_{ico} = [f_{ref\_crystal} \times (MFD + 4)] \div (PREDIV + 1)^{16}   f_{ico} = [f_{ref\_ext} \times (MFD + 4)] \div (PREDIV + 1)$                      | f <sub>ico</sub>    | 48      | 80 <sup>17</sup> | MHz                      |
| 22   | Predivider output frequency (to PLL)  | f <sub>PREDIV</sub> | 4       | 20 <sup>18</sup> | MHz                      |

Nominal crystal and external reference values are worst-case not more than 1%. The device operates correctly if the frequency remains within ± 5% of the specification limit. This tolerance range allows for a slight frequency drift of the crystals over time. The designer must thoroughly understand the drift margin of the source clock.

- The PLL operates at self-clocked mode (SCM) frequency when the reference frequency falls below f<sub>LOR</sub>. SCM frequency is measured on the CLKOUT ball with the divider set to divide-by-two of the system clock.
  NOTE: In SCM, the MFD and PREDIV have no effect and the RFD is bypassed.
- <sup>6</sup> Use the EXTAL input high voltage parameter when using the FlexCAN oscillator in crystal mode (no quartz crystals or resonators). (V<sub>extal</sub> V<sub>xtal</sub>) must be ≥ 400 mV for the oscillator's comparator to produce the output clock.
- Use the EXTAL input low voltage parameter when using the FlexCAN oscillator in crystal mode (no quartz crystals or resonators). (V<sub>xtal</sub> − V<sub>extal</sub>) must be ≥ 400 mV for the oscillator's comparator to produce the output clock.
- 8 I<sub>xtal</sub> is the oscillator bias current out of the XTAL pin with both EXTAL and XTAL pins grounded.
- <sup>9</sup> C<sub>PCB EXTAL</sub> and C<sub>PCB XTAL</sub> are the measured PCB stray capacitances on EXTAL and XTAL, respectively.
- <sup>10</sup> This specification applies to the period required for the PLL to relock after changing the MFD frequency control bits in the synthesizer control register (SYNCR). From power up with crystal oscillator reference, the lock time also includes the crystal startup time.

MPC5534 Microcontroller Data Sheet, Rev. 5

<sup>&</sup>lt;sup>2</sup> All internal registers retain data at 0 Hz.

<sup>&</sup>lt;sup>3</sup> Up to the maximum frequency rating of the device (refer to Table 1).

Loss of reference frequency is defined as the reference frequency detected internally, which transitions the PLL into self-clocked mode.

<sup>&</sup>lt;sup>11</sup> PLL is operating in 1:1 PLL mode.

 $<sup>^{12}</sup>$  V<sub>DDF</sub> = 3.0–3.6 V.

<sup>&</sup>lt;sup>13</sup> Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f<sub>sys</sub>. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the PLL circuitry via V<sub>DDSYN</sub> and V<sub>SSSYN</sub> and variation in crystal oscillator frequency increase the jitter percentage for a given interval. CLKOUT divider is set to divide-by-two.

<sup>&</sup>lt;sup>14</sup> Values are with frequency modulation disabled. If frequency modulation is enabled, jitter is the sum of (jitter + Cmod).

 $<sup>^{15}</sup>$  Modulation depth selected must not result in  $f_{svs}$  value greater than the  $f_{svs}$  maximum specified value.

 $<sup>^{16}</sup> f_{SVS} = f_{iCO} \div (2^{RFD}).$ 

<sup>&</sup>lt;sup>17</sup> The ICO frequency can be higher than the maximum allowable system frequency. For this case, set the FMPLL synthesizer control register reduced frequency divider (FMPLL\_SYNCR[RFD]) to divide-by-two (RFD = 0b001). Therefore, for a 40 MHz maximum device (system frequency), program the FMPLL to generate 80 MHz at the ICO output and then divide-by-two the RFD to provide the 40 MHz clock.

<sup>&</sup>lt;sup>18</sup> Maximum value for dual controller (1:1) mode is  $(f_{MAX} \div 2)$  with the predivider set to 1 (FMPLL\_SYNCR[PREDIV] = 0b001).

#### 3.10 eQADC Electrical Characteristics

Table 13. eQADC Conversion Specifications ( $T_A = T_L$  to  $T_H$ )

| Spec | Characteristic   | Symbol             | Minimum                    | Maximum                          | Unit                |
|------|--|--------------------|----------------------------|----------------------------------|---------------------|
| 1    | ADC clock (ADCLK) frequency <sup>1</sup>   | F <sub>ADCLK</sub> | 1                          | 12                               | MHz                 |
| 2    | Conversion cycles Differential Single ended  | CC                 | 13 + 2 (15)<br>14 + 2 (16) | 13 + 128 (141)<br>14 + 128 (142) | ADCLK<br>cycles     |
| 3    | Stop mode recovery time <sup>2</sup>   | T <sub>SR</sub>    | 10                         | _                                | μS                  |
| 4    | Resolution <sup>3</sup>  | _                  | 1.25                       | _                                | mV                  |
| 5    | INL: 6 MHz ADC clock   | INL6               | -4                         | 4                                | Counts <sup>3</sup> |
| 6    | INL: 12 MHz ADC clock  | INL12              | -8                         | 8                                | Counts              |
| 7    | DNL: 6 MHz ADC clock   | DNL6               | -3 <sup>4</sup>            | 3 <sup>4</sup>                   | Counts              |
| 8    | DNL: 12 MHz ADC clock  | DNL12              | -6 <sup>4</sup>            | 6 <sup>4</sup>                   | Counts              |
| 9    | Offset error with calibration  | OFFWC              | -4 <sup>5</sup>            | 4 <sup>5</sup>                   | Counts              |
| 10   | Full-scale gain error with calibration   | GAINWC             | -8 <sup>6</sup>            | 8 <sup>6</sup>                   | Counts              |
| 11   | Disruptive input injection current <sup>7, 8, 9, 10</sup>  | I <sub>INJ</sub>   | -1                         | 1                                | mA                  |
| 12   | Incremental error due to injection current. All channels are 10 k $\Omega$ < Rs <100 k $\Omega$ Channel under test has Rs = 10 k $\Omega$ , $I_{\text{INJ}} = I_{\text{INJMAX}}$ , $I_{\text{INJMIN}}$ | E <sub>INJ</sub>   | -4                         | 4                                | Counts              |
| 13   | Total unadjusted error (TUE) for single ended conversions with calibration <sup>11, 12, 13, 14, 15</sup>   | TUE                | -4                         | 4                                | Counts              |

Conversion characteristics vary with F<sub>ADCLK</sub> rate. Reduced conversion accuracy occurs at maximum F<sub>ADCLK</sub> rate. The maximum value is based on 800 KS/s and the minimum value is based on 20 MHz oscillator clock frequency divided by a maximum 16 factor.

Stop mode recovery time begins when the ADC control register enable bits are set until the ADC is ready to perform conversions.

<sup>&</sup>lt;sup>3</sup> At  $V_{RH} - V_{RI} = 5.12$  V, one least significant bit (LSB) = 1.25, mV = one count.

<sup>&</sup>lt;sup>4</sup> Guaranteed 10-bit mono tonicity.

<sup>&</sup>lt;sup>5</sup> The absolute value of the offset error without calibration ≤ 100 counts.

<sup>&</sup>lt;sup>6</sup> The absolute value of the full scale gain error without calibration ≤ 120 counts.

Below disruptive current conditions, the channel being stressed has conversion values of: 0x3FF for analog inputs greater than V<sub>RH</sub>, and 0x000 for values less than V<sub>RL</sub>. This assumes that V<sub>RH</sub> ≤ V<sub>DDA</sub> and V<sub>RL</sub> ≥ V<sub>SSA</sub> due to the presence of the sample amplifier. Other channels are not affected by non-disruptive conditions.

Exceeding the limit can cause a conversion error on both stressed and unstressed channels. Transitions within the limit do not affect device reliability or cause permanent damage.

Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values using V<sub>POSCLAMP</sub> = V<sub>DDA</sub> + 0.5 V and V<sub>NEGCLAMP</sub> = - 0.3 V, then use the larger of the calculated values.

<sup>&</sup>lt;sup>10</sup> This condition applies to two adjacent pads on the internal pad.

<sup>&</sup>lt;sup>11</sup> The TUE specification is always less than the sum of the INL, DNL, offset, and gain errors due to canceling errors.

<sup>&</sup>lt;sup>12</sup> TUE does not apply to differential conversions.

<sup>&</sup>lt;sup>13</sup> Measured at 6 MHz ADC clock. TUE with a 12 MHz ADC clock is: –16 counts < TUE < 16 counts.

<sup>&</sup>lt;sup>14</sup> TUE includes all internal device errors such as internal reference variation (75% Ref, 25% Ref).

<sup>&</sup>lt;sup>15</sup> Depending on the input impedance, the analog input leakage current (Table 9. DC Electrical Specifications, spec 35a) can affect the actual TUE measured on analog channels AN[12], AN[13], AN[14], AN[15].

# 3.11 H7Fb Flash Memory Electrical Characteristics

Table 14. Flash Program and Erase Specifications ( $T_A = T_L$  to  $T_H$ )

| Spec | Flash Program Characteristic  | Symbol                   | Min. | Typical <sup>1</sup> | Initial<br>Max. <sup>2</sup> | Max. <sup>3</sup> | Unit |
|------|---|--------------------------|------|----------------------|------------------------------|-------------------|------|
| 3    | Doubleword (64 bits) program time <sup>4</sup>                            | T <sub>dwprogram</sub>   | _    | 10                   | _                            | 500               | μS   |
| 4    | Page program time <sup>4</sup>  | T <sub>pprogram</sub>    | _    | 22                   | 44 <sup>5</sup>              | 500               | μS   |
| 7    | 16 KB block pre-program and erase time                                    | T <sub>16kpperase</sub>  | _    | 325                  | 525                          | 5000              | ms   |
| 9    | 48 KB block pre-program and erase time                                    | T <sub>48kpperase</sub>  | _    | 435                  | 525                          | 5000              | ms   |
| 10   | 64 KB block pre-program and erase time                                    | T <sub>64kpperase</sub>  | _    | 525                  | 675                          | 5000              | ms   |
| 8    | 128 KB block pre-program and erase time                                   | T <sub>128kpperase</sub> | _    | 675                  | 1800                         | 7500              | ms   |
| 11   | Minimum operating frequency for program and erase operations <sup>6</sup> | _                        | 25   | _                    | _                            | _                 | MHz  |

Typical program and erase times are calculated at 25 °C operating temperature using nominal supply values.

Table 15. Flash EEPROM Module Life  $(T_A = T_L \text{ to } T_H)$ 

| Spec | Characteristic   | Symbol    | Min.    | Typical <sup>1</sup> | Unit   |
|------|--|-----------|---------|----------------------|--------|
| 1a   | Number of program/erase cycles per block for 16 KB, 48 KB, and 64 KB blocks over the operating temperature range (T <sub>J</sub> ) | P/E       | 100,000 | _                    | cycles |
| 1b   | Number of program/erase cycles per block for 128 KB blocks over the operating temperature range ( $T_{\rm J}$ )                    | P/E       | 1000    | 100,000              | cycles |
| 2    | Data retention Blocks with 0–1,000 P/E cycles Blocks with 1,001–100,000 P/E cycles   | Retention | 20<br>5 | _<br>_               | years  |

Typical endurance is evaluated at 25° C. Product qualification is performed to the minimum specification. For additional information on the Freescale definition of typical endurance, refer to engineering bulletin EB619 Typical Endurance for Nonvolatile Memory.

Initial factory condition: ≤ 100 program/erase cycles, 25 °C, using a typical supply voltage measured at a minimum system frequency of 80 MHz.

The maximum erase time occurs after the specified number of program/erase cycles. This maximum value is characterized but not guaranteed.

<sup>&</sup>lt;sup>4</sup> Actual hardware programming times. This does not include software overhead.

<sup>&</sup>lt;sup>5</sup> Page size is 128 bits (4 words).

<sup>&</sup>lt;sup>6</sup> The read frequency of the flash can range up to the maximum operating frequency. There is no minimum read frequency condition.

Table 16 shows the FLASH\_BIU settings versus frequency of operation. Refer to the device reference manual for definitions of these bit fields.

Table 16. FLASH\_BIU Settings vs. Frequency of Operation<sup>1</sup>

| Target Maximum Frequency (MHz)             | APC                | RWSC               | wwsc | DPFEN <sup>2</sup> | IPFEN <sup>2</sup> | PFLIM <sup>3</sup>   | BFEN <sup>2</sup> |
|--|--------------------|--------------------|------|--------------------|--------------------|----------------------|-------------------|
| Up to and including 27 MHz <sup>4, 5</sup> | 0b000              | 0b000              | 0b01 | 0b0<br>0b1         | 0b0<br>0b1         | 0b000<br>to<br>0b010 | 0b0<br>0b1        |
| Up to and including 52 MHz <sup>6</sup>    | 0b001              | 0b001              | 0b01 | 0b0<br>0b1         | 0b0<br>0b1         | 0b000<br>to<br>0b010 | 0b0<br>0b1        |
| Up to and including 77 MHz <sup>7</sup>    | 0b010              | 0b010              | 0b01 | 0b0<br>0b1         | 0b0<br>0b1         | 0b000<br>to<br>0b010 | 0b0<br>0b1        |
| Up to and including 82 MHz <sup>8</sup>    | 0b011 <sup>9</sup> | 0b011 <sup>9</sup> | 0b01 | 0b0<br>0b1         | 0b0<br>0b1         | 0b000<br>to<br>0b010 | 0b0<br>0b1        |
| Reset values:                              | 0b111              | 0b111              | 0b11 | 0b0                | 0b0                | 0b000                | 0b0               |

<sup>&</sup>lt;sup>1</sup> Illegal combinations exist. Use entries from the same row in this table.

# 3.12 AC Specifications

#### 3.12.1 Pad AC Specifications

Table 17. Pad AC Specifications ( $V_{DDEH} = 5.0 \text{ V}, V_{DDE} = 1.8 \text{ V}$ ) <sup>1</sup>

| Spec | Pad                    | SRC / DSC<br>(binary) | Out Delay <sup>2, 3, 4</sup> (ns) | Rise / Fall <sup>4, 5</sup><br>(ns) | Load Drive<br>(pF) |
|------|------------------------|-----------------------|-----------------------------------|-------------------------------------|--------------------|
|      | Slow high voltage (SH) | 11                    | 26                                | 15                                  | 50                 |
|      |                        |                       | 82                                | 60                                  | 200                |
| 1    |                        | 01                    | 75                                | 40                                  | 50                 |
| '    |                        |                       | 137                               | 80                                  | 200                |
|      |                        | 00                    | 377                               | 200                                 | 50                 |
|      |                        |                       | 476                               | 260                                 | 200                |

<sup>&</sup>lt;sup>2</sup> For maximum flash performance, set to 0b1.

<sup>&</sup>lt;sup>3</sup> For maximum flash performance, set to 0b010.

<sup>&</sup>lt;sup>4</sup> 27 MHz parts allow for 25 MHz system clock + 2% frequency modulation (FM).

<sup>&</sup>lt;sup>5</sup> The APC, RWSC, and WWSC combination requires setting the PRD bit to 1 in the flash MCR register.

<sup>&</sup>lt;sup>6</sup> 52 MHz parts allow for 50 MHz system clock + 2% FM.

<sup>&</sup>lt;sup>7</sup> 77 MHz parts allow for 75 MHz system clock + 2% FM.

<sup>&</sup>lt;sup>8</sup> 82 MHz parts allow for 80 MHz system clock + 2% FM.

<sup>9</sup> For frequencies up to and including 80 MHz, if VDD is within ±5% of 1.5 V, then APC = RWSC = 0b010 is a valid setting.

Table 17. Pad AC Specifications  $(V_{DDEH} = 5.0 \text{ V}, V_{DDE} = 1.8 \text{ V})^{1}$  (continued)

| Spec | Pad                      | SRC / DSC<br>(binary) | Out Delay <sup>2, 3, 4</sup> (ns) | Rise / Fall <sup>4, 5</sup><br>(ns) | Load Drive<br>(pF) |
|------|--------------------------|-----------------------|-----------------------------------|-------------------------------------|--------------------|
|      |                          | 11                    | 16                                | 8                                   | 50                 |
| 2    |                          |                       | 43                                | 30                                  | 200                |
|      | Medium high voltage (MH) | 01                    | 34                                | 15                                  | 50                 |
|      |                          | 01                    | 61                                | 35                                  | 200                |
|      |                          | 00                    | 192                               | 100                                 | 50                 |
|      |                          |                       | 239                               | 125                                 | 200                |
|      |                          | 00                    |                                   | 2.7                                 | 10                 |
| 3    | Fast                     | 01                    | 3.1                               | 2.5                                 | 20                 |
| 3    | rasi                     | 10                    | 3.1                               | 2.4                                 | 30                 |
|      |                          | 11                    |                                   | 2.3                                 | 50                 |
| 4    | Pullup/down (3.6 V max)  | _                     | _                                 | 7500                                | 50                 |
| 5    | Pullup/down (5.5 V max)  | _                     | _                                 | 9000                                | 50                 |

These are worst-case values that are estimated from simulation (not tested). The values in the table are simulated at:  $V_{DD} = 1.35-1.65 \text{ V}$ ;  $V_{DDE} = 1.62-1.98 \text{ V}$ ;  $V_{DDEH} = 4.5-5.25 \text{ V}$ ;  $V_{DD33}$  and  $V_{DDSYN} = 3.0-3.6 \text{ V}$ ; and  $V_{DDSYN} = 1.05 \text{ V}$ ;  $V_{DDSYN} = 1.05 \text{ V}$ 

Table 18. Derated Pad AC Specifications ( $V_{DDEH} = 3.3 \text{ V}, V_{DDE} = 3.3 \text{ V}$ ) <sup>1</sup>

| Spec | Pad                                | SRC/DSC<br>(binary) | Out Delay <sup>2, 3, 4</sup> (ns) | Rise / Fall <sup>3, 5</sup> (ns) | Load Drive<br>(pF) |
|------|------------------------------------|---------------------|-----------------------------------|----------------------------------|--------------------|
|      |                                    | 11                  | 39                                | 23                               | 50                 |
|      |                                    | 11                  | 120                               | 87                               | 200                |
| 1    | Slow high voltage (SH)             | 01                  | 101                               | 52                               | 50                 |
|      | Slow High Voltage (SH)             | 01                  | 188                               | 111                              | 200                |
|      |                                    | 00                  | 507                               | 248                              | 50                 |
|      |                                    | 00                  | 597                               | 312                              | 200                |
|      |                                    | 11                  | 23                                | 12                               | 50                 |
|      |                                    | 11                  | 64                                | 44                               | 200                |
| 2    | Medium high voltage (MH)           | 01                  | 50                                | 22                               | 50                 |
|      | iviedidiii fiigii voitage (ivii i) | 01                  | 90                                | 50                               | 200                |
|      |                                    | 00                  | 261                               | 123                              | 50                 |
|      |                                    | 00                  | 305                               | 156                              | 200                |

<sup>&</sup>lt;sup>2</sup> This parameter is supplied for reference and is guaranteed by design (not tested).

The output delay is shown in Figure 4. To calculate the output delay with respect to the system clock, add a maximum of one system clock to the output delay.

<sup>&</sup>lt;sup>4</sup> The output delay and rise and fall are measured to 20% or 80% of the respective signal.

<sup>&</sup>lt;sup>5</sup> This parameter is guaranteed by characterization rather than 100% tested.

Table 18. Derated Pad AC Specifications ( $V_{DDEH} = 3.3 \text{ V}$ ,  $V_{DDE} = 3.3 \text{ V}$ ) <sup>1</sup> (continued)

| Spec | Pad                     | SRC/DSC<br>(binary) | Out Delay <sup>2, 3, 4</sup> (ns) | Rise / Fall <sup>3, 5</sup><br>(ns) | Load Drive<br>(pF) |
|------|-------------------------|---------------------|-----------------------------------|-------------------------------------|--------------------|
|      |                         | 00                  |                                   | 2.4                                 | 10                 |
| 3    | Fast                    | 01                  | 3.2                               | 2.2                                 | 20                 |
| 3    | rasi                    | 10                  | 3.2                               | 2.1                                 | 30                 |
|      |                         | 11                  |                                   | 2.1                                 | 50                 |
| 4    | Pullup/down (3.6 V max) | _                   | _                                 | 7500                                | 50                 |
| 5    | Pullup/down (5.5 V max) | _                   | _                                 | 9500                                | 50                 |

These are worst-case values that are estimated from simulation (not tested). The values in the table are simulated at:  $V_{DD} = 1.35-1.65 \text{ V}$ ;  $V_{DDE} = 3.0-3.6 \text{ V}$ ;  $V_{DDEH} = 3.0-3.6 \text{ V}$ ;  $V_{DD33}$  and  $V_{DDSYN} = 3.0-3.6 \text{ V}$ ; and  $V_{DDSYN} = 0.00$ .

<sup>&</sup>lt;sup>5</sup> This parameter is guaranteed by characterization rather than 100% tested.

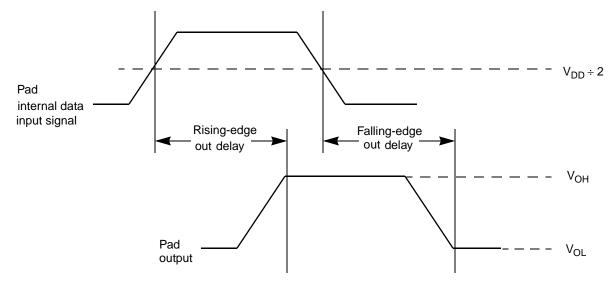


Figure 4. Pad Output Delay

# 3.13 AC Timing

# 3.13.1 Reset and Configuration Pin Timing

Table 19. Reset and Configuration Pin Timing <sup>1</sup>

| Spec | Characteristic                  | Symbol           | Min. | Max. | Unit             |
|------|---------------------------------|------------------|------|------|------------------|
| 1    | RESET pulse width               | t <sub>RPW</sub> | 10   | _    | t <sub>CYC</sub> |
| 2    | RESET glitch detect pulse width | t <sub>GPW</sub> | 2    | _    | t <sub>CYC</sub> |

#### MPC5534 Microcontroller Data Sheet, Rev. 5

<sup>&</sup>lt;sup>2</sup> This parameter is supplied for reference and guaranteed by design (not tested).

<sup>&</sup>lt;sup>3</sup> The output delay, and the rise and fall, are calculated to 20% or 80% of the respective signal.

The output delay is shown in Figure 4. To calculate the output delay with respect to the system clock, add a maximum of one system clock to the output delay.

Table 19. Reset and Configuration Pin Timing <sup>1</sup> (continued)

| Spec | Characteristic  | Symbol            | Min. | Max. | Unit             |
|------|---|-------------------|------|------|------------------|
| 3    | PLLCFG, BOOTCFG, WKPCFG, RSTCFG setup time to RSTOUT valid  | t <sub>RCSU</sub> | 10   |      | t <sub>CYC</sub> |
| 4    | PLLCFG, BOOTCFG, WKPCFG, RSTCFG hold time from RSTOUT valid | t <sub>RCH</sub>  | 0    |      | t <sub>CYC</sub> |

<sup>1</sup> Reset timing specified at:  $V_{DDEH} = 3.0-5.25 \text{ V}$  and  $T_A = T_L \text{ to } T_H$ .

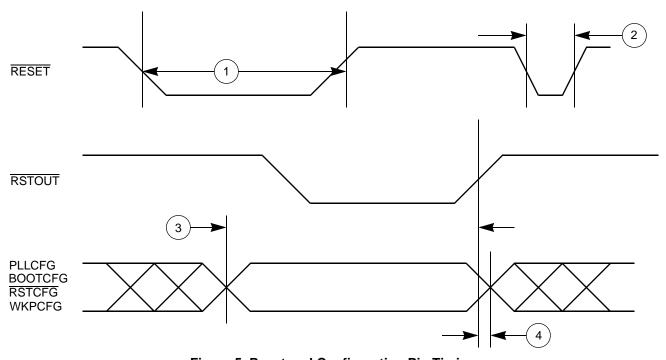


Figure 5. Reset and Configuration Pin Timing

# 3.13.2 IEEE 1149.1 Interface Timing

Table 20. JTAG Pin AC Electrical Characteristics <sup>1</sup>

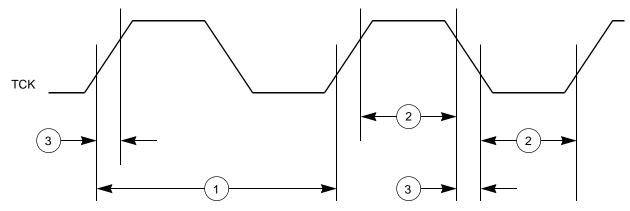
| Spec | Characteristic   | Symbol                                | Min. | Max. | Unit |
|------|--|---------------------------------------|------|------|------|
| 1    | TCK cycle time   | t <sub>JCYC</sub>                     | 100  | _    | ns   |
| 2    | TCK clock pulse width (measured at V <sub>DDE</sub> ÷ 2) | t <sub>JDC</sub>                      | 40   | 60   | ns   |
| 3    | TCK rise and fall times (40% to 70%)                     | t <sub>TCKRISE</sub>                  |      | 3    | ns   |
| 4    | TMS, TDI data setup time                                 | t <sub>TMSS</sub> , t <sub>TDIS</sub> | 5    | _    | ns   |
| 5    | TMS, TDI data hold time                                  | t <sub>TMSH</sub> , t <sub>TDIH</sub> | 25   | 1    | ns   |
| 6    | TCK low to TDO data valid                                | t <sub>TDOV</sub>                     |      | 20   | ns   |
| 7    | TCK low to TDO data invalid                              | t <sub>TDOI</sub>                     | 0    | _    | ns   |
| 8    | TCK low to TDO high impedance                            | t <sub>TDOHZ</sub>                    | _    | 20   | ns   |
| 9    | JCOMP assertion time                                     | t <sub>JCMPPW</sub>                   | 100  | _    | ns   |
| 10   | JCOMP setup time to TCK low                              | t <sub>JCMPS</sub>                    | 40   | _    | ns   |
| 11   | TCK falling-edge to output valid                         | t <sub>BSDV</sub>                     | _    | 50   | ns   |

MPC5534 Microcontroller Data Sheet, Rev. 5

Table 20. JTAG Pin AC Electrical Characteristics <sup>1</sup> (continued)

| Spec | Characteristic   | Symbol             | Min. | Max. | Unit |
|------|--|--------------------|------|------|------|
| 12   | TCK falling-edge to output valid out of high impedance | t <sub>BSDVZ</sub> | _    | 50   | ns   |
| 13   | TCK falling-edge to output high impedance (Hi-Z)       | t <sub>BSDHZ</sub> | _    | 50   | ns   |
| 14   | Boundary scan input valid to TCK rising-edge           | t <sub>BSDST</sub> | 50   | _    | ns   |
| 15   | TCK rising-edge to boundary scan input invalid         | t <sub>BSDHT</sub> | 50   | 1    | ns   |

<sup>&</sup>lt;sup>1</sup> These specifications apply to JTAG boundary scan only. JTAG timing specified at:  $V_{DDE} = 3.0-3.6 \text{ V}$  and  $T_A = T_L$  to  $T_H$ . Refer to Table 21 for Nexus specifications.



**Figure 6. JTAG Test Clock Input Timing** 

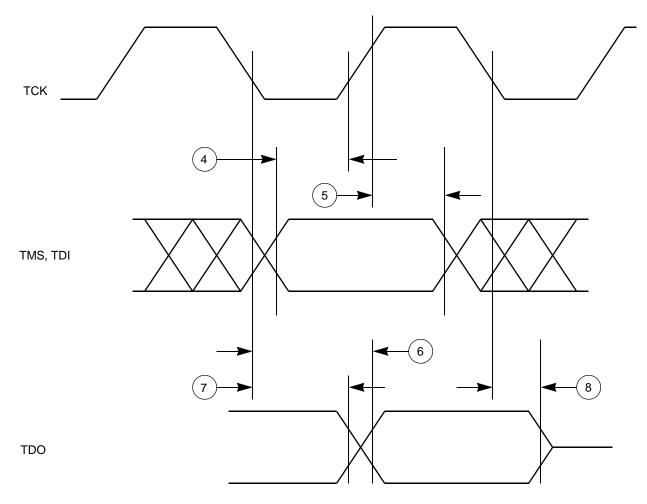
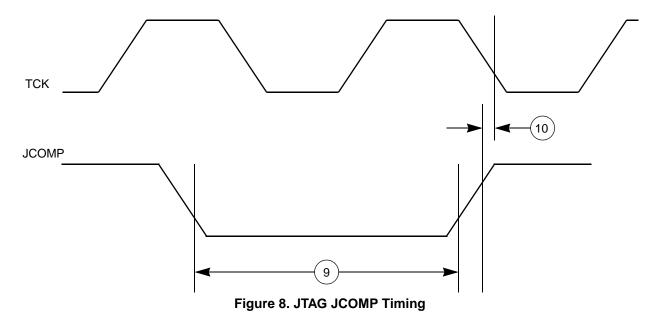


Figure 7. JTAG Test Access Port Timing



MPC5534 Microcontroller Data Sheet, Rev. 5

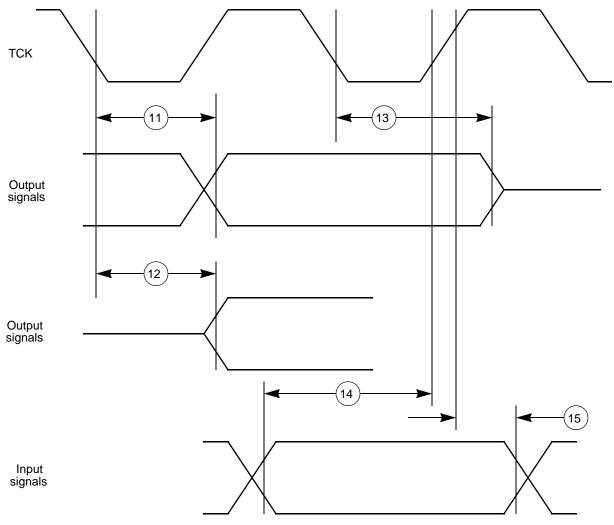


Figure 9. JTAG Boundary Scan Timing

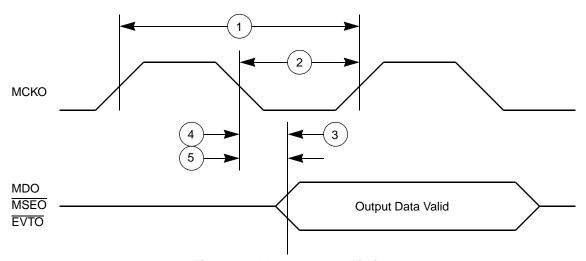
#### 3.13.3 Nexus Timing

Table 21. Nexus Debug Port Timing <sup>1</sup>

| Spec | Characteristic                           | Symbol                                  | Min.           | Max. | Unit              |
|------|--|---|----------------|------|-------------------|
| 1    | MCKO cycle time                          | t <sub>MCYC</sub>                       | 1 <sup>2</sup> | 8    | t <sub>CYC</sub>  |
| 2    | MCKO duty cycle                          | t <sub>MDC</sub>                        | 40             | 60   | %                 |
| 3    | MCKO low to MDO data valid <sup>3</sup>  | t <sub>MDOV</sub>                       | -1.5           | 3.0  | ns                |
| 4    | MCKO low to MSEO data valid <sup>3</sup> | t <sub>MSEOV</sub>                      | -1.5           | 3.0  | ns                |
| 5    | MCKO low to EVTO data valid <sup>3</sup> | t <sub>EVTOV</sub>                      | -1.5           | 3.0  | ns                |
| 6    | EVTI pulse width                         | t <sub>EVTIPW</sub>                     | 4.0            | _    | t <sub>TCYC</sub> |
| 7    | EVTO pulse width                         | t <sub>EVTOPW</sub>                     | 1              | _    | t <sub>MCYC</sub> |
| 8    | TCK cycle time                           | t <sub>TCYC</sub>                       | 4 4            | _    | t <sub>CYC</sub>  |
| 9    | TCK duty cycle                           | t <sub>TDC</sub>                        | 40             | 60   | %                 |
| 10   | TDI, TMS data setup time                 | t <sub>NTDIS</sub> , t <sub>NTMSS</sub> | 8              | _    | ns                |
| 11   | TDI, TMS data hold time                  | t <sub>NTDIH</sub> , t <sub>NTMSH</sub> | 5              | _    | ns                |
|      | TCK low to TDO data valid                | t <sub>JOV</sub>                        |                |      |                   |
| 12   | $V_{DDE} = 2.25-3.0 \text{ V}$           |   | 0              | 12   | ns                |
|      | $V_{DDE} = 3.0-3.6 \text{ V}$            |   | 0              | 10   | ns                |
| 13   | RDY valid to MCKO <sup>5</sup>           | _                                       | _              | _    | _                 |

<sup>&</sup>lt;sup>1</sup> JTAG specifications apply when used for debug functionality. All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal. Nexus timing specified at  $V_{DD} = 1.35-1.65 \text{ V}$ ,  $V_{DDE} = 2.25-3.6 \text{ V}$ ,  $V_{DD33}$  and  $V_{DDSYN} = 3.0-3.6 \text{ V}$ ,  $V_{A} = V_{A}$  and  $V_{A} = V_{A}$  a

<sup>&</sup>lt;sup>5</sup> The RDY pin timing is asynchronous to MCKO and is guaranteed by design to function correctly.



**Figure 10. Nexus Output Timing** 

MPC5534 Microcontroller Data Sheet, Rev. 5

<sup>&</sup>lt;sup>2</sup> The Nexus AUX port runs up to 82 MHz.

 $<sup>^3</sup>$  MDO,  $\overline{\text{MSEO}}$ , and  $\overline{\text{EVTO}}$  data is held valid until the next MCKO low cycle occurs.

Limit the maximum frequency to approximately 16 MHz (V<sub>DDE</sub> = 2.25–3.0 V) or 20 MHz (V<sub>DDE</sub> = 3.0–3.6 V) to meet the timing specification for t<sub>JOV</sub> of [0.2 x t<sub>JCYC</sub>] as outlined in the IEEE-ISTO 5001-2003 specification.

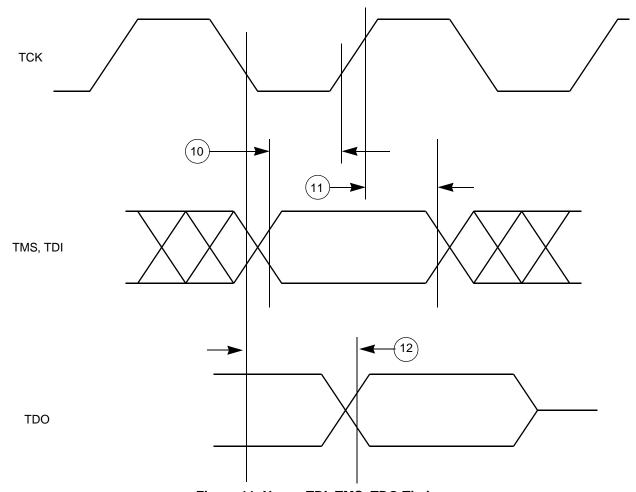


Figure 11. Nexus TDI, TMS, TDO Timing

# 3.13.4 External Bus Interface (EBI) Timing

Table 22 lists the timing information for the external bus interface (EBI).

Table 22. External Bus Operation Timing 1, 2

|                | Characteristic  |                   |                         | External Bus Frequency <sup>3</sup> |                         |                   |                         |                   |                |   |
|----------------|---|-------------------|-------------------------|-------------------------------------|-------------------------|-------------------|-------------------------|-------------------|----------------|---|
| Spec           | and   | Symbol            | 20                      | ИНz                                 | 33 I                    | ИHz               | 40 N                    | ИHz               | Unit           | Notes   |
|                | Description   |                   | Min.                    | Max                                 | Min.                    | Max               | Min.                    | Max               |                |   |
| 1              | CLKOUT period   | T <sub>C</sub>    | 24.4                    | _                                   | 17.5                    | _                 | 14.9                    | _                 | ns             | Signals are measured at 50% V <sub>DDE</sub> .        |
| 2              | CLKOUT duty cycle   | t <sub>CDC</sub>  | 45%                     | 55%                                 | 45%                     | 55%               | 45%                     | 55%               | T <sub>C</sub> |   |
| 3              | CLKOUT rise time  | t <sub>CRT</sub>  | _                       | 4                                   | _                       | _                 | _                       | 4                 | ns             |   |
| 4              | CLKOUT fall time  | t <sub>CFT</sub>  | _                       | 4                                   | _                       | 4                 | _                       | 4                 | ns             |   |
|                | CLKOUT positive edge to output signal <i>invalid</i> or Hi-Z (hold time)  External bus interface  CS[0:3] | tсон              | 1.0 <sup>6</sup><br>1.5 | _                                   | 1.0 <sup>6</sup><br>1.5 | _                 | 1.0 <sup>6</sup><br>1.5 | _                 | ns             | EBTS = 0  EBTS = 1  Hold time selectable via SIU_ECCR |
| 5 <sup>5</sup> | ADDR[8:31] DATA[0:15] RD_WR BDIP WE/BE[0:1] OE TS TA  |                   |                         |                                     |                         |                   |                         |                   |                | [EBTS] bit.   |
| -              | Calibration bus interface<br>CAL_CS[0, 2:3]<br>CAL_ADDR[10:30]<br>CAL_DATA[0:15]                          | t <sub>CCOH</sub> | 1.0 <sup>6</sup><br>1.5 | _                                   | 1.0 <sup>6</sup>        | _                 | 1.0 <sup>6</sup>        | _                 | ns             | EBTS = 0<br>EBTS = 1                                  |
| 5              | CAL_RD_WR CAL_WE[0:1] CAL_OE CAL_TS   |                   |                         |                                     |                         |                   |                         |                   |                | Hold time selectable via SIU_ECCR [EBTS] bit.         |
|                | CLKOUT positive edge to output signal <i>valid</i> (output delay)   | t <sub>COV</sub>  | _                       | 10.0 <sup>6</sup>                   | _                       | 10.0 <sup>6</sup> | _                       | 10.0 <sup>6</sup> | ns             | EBTS = 0<br>EBTS = 1                                  |
| 6 <sup>5</sup> | External bus interface  CS[0:3]  ADDR[8:31]  DATA[0:15]  RD_WR  BDIP  WE/BE[0:1]  OE TS TA                |                   |                         | 11.0                                |                         | 11.0              |                         | 11.0              |                | Output valid time selectable via SIU_ECCR [EBTS] bit. |

Table 22. External Bus Operation Timing<sup>1, 2</sup> (continued)

|                 | Characteristic<br>and<br>Description  |                   | External Bus Frequency <sup>3</sup> |                           |        |                           |      |                           |      |                                       |  |
|-----------------|---|-------------------|-------------------------------------|---------------------------|--------|---------------------------|------|---------------------------|------|---------------------------------------|--|
| Spec            |   | Symbol            | 20 MHz                              |                           | 33 MHz |                           | 40 l | ИHz                       | Unit | Notes                                 |  |
|                 | Description   |                   | Min.                                | Max                       | Min.   | Max                       | Min. | Max                       |      |                                       |  |
|                 | CLKOUT positive edge to output signal valid (output delay)  Calibration bus interface | tccov             | _                                   | 11.0 <sup>6</sup><br>12.0 | _      | 11.0 <sup>6</sup><br>12.0 | _    | 11.0 <sup>6</sup><br>12.0 | ns   | EBTS = 0  EBTS = 1  Output valid time |  |
| 6a <sup>5</sup> | CAL_CS[0, 2:3] CAL_ADDR[10:30] CAL_DATA[0:15] CAL_RD_WR CAL_WE[0:1] CAL_OE CAL_TS     |                   |                                     |                           |        |                           |      |                           |      | selectable via SIU_ECCR [EBTS] bit.   |  |
|                 | Input signal valid to CLKOUT positive edge (setup time)                               |                   |                                     |                           |        |                           |      |                           |      |                                       |  |
| 7 <sup>5</sup>  | External bus interface<br>ADDR[8:31]<br>DATA[0:15]<br>RD_WR<br>TS<br>TA               | <sup>t</sup> CIS  | 10.0                                | _                         | 10.0   | _                         | 10.0 | _                         | ns   |                                       |  |
|                 | Input signal valid to CLKOUT positive edge (setup time)                               |                   |                                     |                           |        |                           |      |                           |      |                                       |  |
| 5               | Calibration bus interface CAL_ADDR[10:30] CAL_DATA[0:15] CAL_RD_WR CAL_TS             | <sup>t</sup> ccis | 11.0                                |                           | 11.0   |                           | 11.0 | _                         | ns   |                                       |  |
|                 | CLKOUT positive edge to input signal invalid (hold time)                              |                   |                                     |                           |        |                           |      |                           |      |                                       |  |
| 8 <sup>5</sup>  | External bus interface ADDR[8:31] DATA[0:15] RD_WR TS TA                              | <sup>t</sup> CIH  | 1.0                                 | _                         | 1.0    | _                         | 1.0  | _                         | ns   |                                       |  |
| 5               | Calibration bus interface CAL_ADDR[10:30] CAL_DATA[0:15] CAL_RD_WR CAL_TS             | <sup>t</sup> CCIH | 1.0                                 | _                         | 1.0    | _                         | 1.0  | _                         | ns   |                                       |  |

- Speed is the nominal maximum frequency. Max speed is the maximum speed allowed including frequency modulation (FM). 42 MHz parts allow for 40 MHz system clock + 2% FM; 68 MHz parts allow for a 66 MHz system clock + 2% FM, and 82 MHz parts allow for 80 MHz system clock + 2% FM.
- <sup>4</sup> Refer to fast pad timing in Table 17 and Table 18 (different values for 1.8 V and 3.3 V).
- <sup>5</sup> Available on the 324 package only; not available on the 208 package.
- $^{6}$  EBTS = 0 timings are tested and valid at  $V_{DDE}$  = 2.25–3.6 V only; EBTS = 1 timings are tested and valid at  $V_{DDE}$  = 1.6–3.6 V.

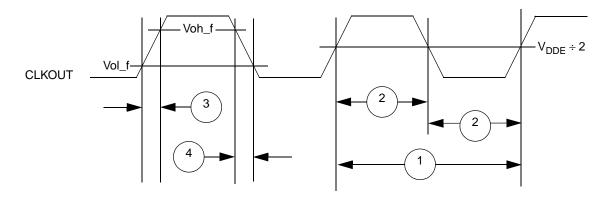
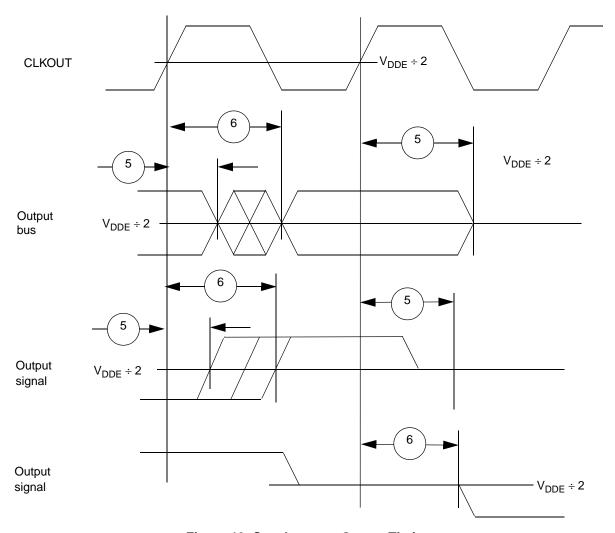
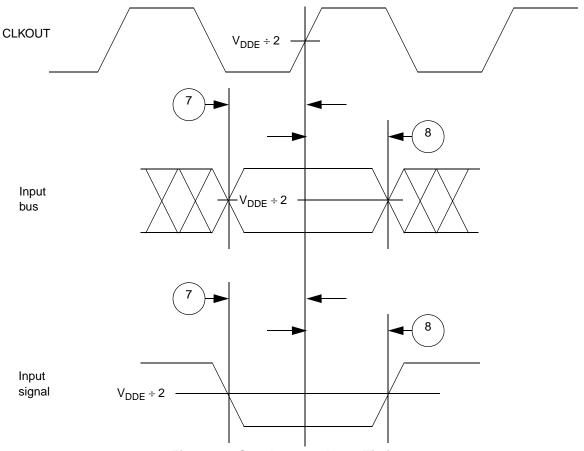


Figure 12. CLKOUT Timing



**Figure 13. Synchronous Output Timing** 



**Figure 14. Synchronous Input Timing** 

#### **External Interrupt Timing (IRQ Signals)** 3.13.5

Table 23. External Interrupt Timing <sup>1</sup>

| Spec | Characteristic                     | Symbol            | Min. | Max. | Unit             |
|------|------------------------------------|-------------------|------|------|------------------|
| 1    | IRQ pulse-width low                | t <sub>IPWL</sub> | 3    | _    | t <sub>CYC</sub> |
| 2    | IRQ pulse-width high               | T <sub>IPWH</sub> | 3    | _    | t <sub>CYC</sub> |
| 3    | IRQ edge-to-edge time <sup>2</sup> | t <sub>ICYC</sub> | 6    | _    | t <sub>CYC</sub> |

MPC5534 Microcontroller Data Sheet, Rev. 5

IRQ timing specified at: V<sub>DDEH</sub> = 3.0–5.25 V and T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>.
 Applies when IRQ signals are configured for rising-edge or falling-edge events, but not both.

#### **Electrical Characteristics**

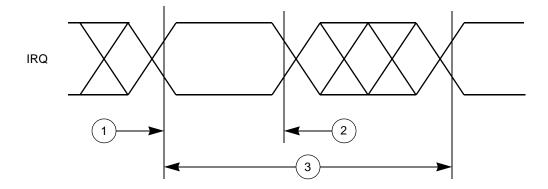


Figure 15. External Interrupt Timing

## 3.13.6 eTPU Timing

Table 24. eTPU Timing <sup>1</sup>

| Spec | Characteristic                  | Symbol            | Min.           | Max | Unit             |
|------|---------------------------------|-------------------|----------------|-----|------------------|
| 1    | eTPU input channel pulse width  | t <sub>ICPW</sub> | 4              | _   | t <sub>CYC</sub> |
| 2    | eTPU output channel pulse width | t <sub>OCPW</sub> | 2 <sup>2</sup> | _   | t <sub>CYC</sub> |

eTPU timing specified at:  $V_{DDEH} = 3.0-5.25 \text{ V}$  and  $T_A = T_L$  to  $T_H$ .

This specification does not include the rise and fall times. When calculating the minimum eTPU pulse width, include the rise and fall times defined in the slew rate control fields (SRC) of the pad configuration registers (PCR).

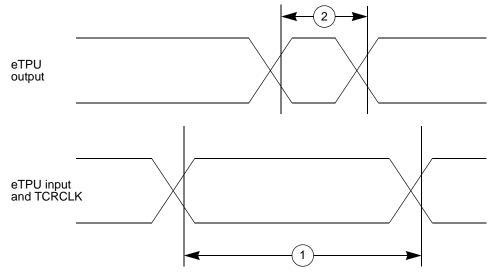


Figure 16. eTPU Timing

MPC5534 Microcontroller Data Sheet, Rev. 5

## 3.13.7 eMIOS Timing

Table 25. eMIOS Timing <sup>1</sup>

| Spec | Characteristic           | Symbol            | Min.           | Max. | Unit             |
|------|--------------------------|-------------------|----------------|------|------------------|
| 1    | eMIOS input pulse width  | t <sub>MIPW</sub> | 4              | _    | t <sub>CYC</sub> |
| 2    | eMIOS output pulse width | t <sub>MOPW</sub> | 1 <sup>2</sup> | _    | t <sub>CYC</sub> |

eMIOS timing specified at:  $V_{DDEH} = 3.0-5.25 \text{ V}$  and  $T_A = T_L$  to  $T_H$ .

<sup>&</sup>lt;sup>2</sup> This specification does not include the rise and fall times. When calculating the minimum eMIOS pulse width, include the rise and fall times defined in the slew rate control field (SRC) in the pad configuration register (PCR).

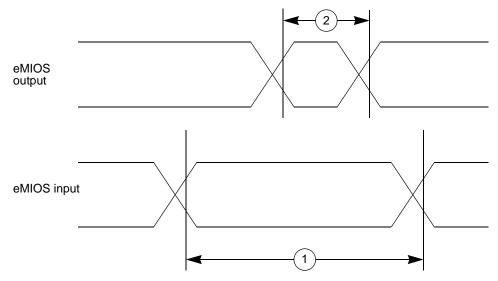


Figure 17. eMIOS Timing

## 3.13.8 DSPI Timing

Table 26. DSPI Timing 1, 2

| Spec Characteristic |  | 40 MHz<br>Symbol  |                                  | 66 MHz                           |                                  | 80 MHz                           |                                  | Unit                             |    |
|---------------------|--|-------------------|----------------------------------|----------------------------------|----------------------------------|----------------------------------|----------------------------------|----------------------------------|----|
| Situation 5         | Symbol   | Min.              | Max                              | Min.                             | Max                              | Min.                             | Max                              | Oilit                            |    |
| 1                   | SCK cycle time <sup>3, 4</sup>                                 | t <sub>SCK</sub>  | 48.8 ns                          | 5.8 ms                           | 28.4 ns                          | 3.5 ms                           | 24.4 ns                          | 2.9 ms                           | _  |
| 2                   | PCS to SCK delay <sup>5</sup>                                  | t <sub>CSC</sub>  | 46                               | _                                | 26                               | _                                | 22                               | _                                | ns |
| 3                   | After SCK delay <sup>6</sup>                                   | t <sub>ASC</sub>  | 45                               | _                                | 25                               | _                                | 21                               | _                                | ns |
| 4                   | SCK duty cycle   | t <sub>SDC</sub>  | (t <sub>SCK</sub> ÷ 2)<br>– 2 ns | (t <sub>SCK</sub> ÷ 2)<br>+ 2 ns | (t <sub>SCK</sub> ÷ 2)<br>– 2 ns | (t <sub>SCK</sub> ÷ 2)<br>+ 2 ns | (t <sub>SCK</sub> ÷ 2)<br>– 2 ns | (t <sub>SCK</sub> ÷ 2)<br>+ 2 ns | ns |
| 5                   | Slave access time (SS active to SOUT driven)                   | t <sub>A</sub>    | _                                | 25                               | _                                | 25                               | _                                | 25                               | ns |
| 6                   | Slave SOUT disable time (SS inactive to SOUT Hi-Z, or invalid) | t <sub>DIS</sub>  | _                                | 25                               | _                                | 25                               | _                                | 25                               | ns |
| 7                   | PCSx to PCSS time  | t <sub>PCSC</sub> | 4                                | _                                | 4                                | _                                | 4                                | _                                | ns |

MPC5534 Microcontroller Data Sheet, Rev. 5

#### **Electrical Characteristics**

Table 26. DSPI Timing 1, 2 (continued)

| Snoo | Spec Characteristic   |                   | 40 MHz               |                    | 66 N                 | MHz 80 MH          |                      | ИHz                | Unit                 |
|------|---|-------------------|----------------------|--------------------|----------------------|--------------------|----------------------|--------------------|----------------------|
| Spec | Characteristic  | Symbol            | Min.                 | Max                | Min.                 | Max                | Min.                 | Max                |                      |
| 8    | PCSS to PCSx time   | t <sub>PASC</sub> | 5                    | _                  | 5                    | _                  | 5                    | _                  | ns                   |
| 9    | Data setup time for inputs Master (MTFE = 0) Slave Master (MTFE = 1, CPHA = 0) <sup>7</sup> Master (MTFE = 1, CPHA = 1) | t <sub>SUI</sub>  | 20<br>2<br>-4<br>20  | _<br>_<br>_<br>_   | 20<br>2<br>6<br>20   | _<br>_<br>_<br>_   | 20<br>2<br>8<br>20   | _<br>_<br>_<br>_   | ns<br>ns<br>ns<br>ns |
| 10   | Data hold time for inputs Master (MTFE = 0) Slave Master (MTFE = 1, CPHA = 0) <sup>7</sup> Master (MTFE = 1, CPHA = 1)  | t <sub>HI</sub>   | -4<br>7<br>45<br>-4  | _<br>_<br>_<br>_   | -4<br>7<br>25<br>-4  | _<br>_<br>_<br>_   | -4<br>7<br>21<br>-4  | _<br>_<br>_<br>_   | ns<br>ns<br>ns<br>ns |
| 11   | Data valid (after SCK edge) Master (MTFE = 0) Slave Master (MTFE = 1, CPHA = 0) Master (MTFE = 1, CPHA = 1)             | tsuo              | _<br>_<br>_<br>_     | 5<br>25<br>45<br>5 | _<br>_<br>_<br>_     | 5<br>25<br>25<br>5 | _<br>_<br>_<br>_     | 5<br>25<br>21<br>5 | ns<br>ns<br>ns<br>ns |
| 12   | Data hold time for outputs  Master (MTFE = 0)  Slave  Master (MTFE = 1, CPHA = 0)  Master (MTFE = 1, CPHA = 1)          | tно               | -5<br>5.5<br>8<br>-5 | _<br>_<br>_<br>_   | -5<br>5.5<br>4<br>-5 | _<br>_<br>_<br>_   | -5<br>5.5<br>3<br>-5 | _<br>_<br>_<br>_   | ns<br>ns<br>ns<br>ns |

All DSPI timing specifications use the fastest slew rate (SRC = 0b11) on pad type M or MH. DSPI signals using pad types of S or SH have an additional delay based on the slew rate. DSPI timing is specified at  $V_{DDEH} = 3.0-5.25 \text{ V}$ ,  $T_A = T_L$  to  $T_H$ , and CL = 50 pF with SRC = 0b11.

Speed is the nominal maximum frequency. Max speed is the maximum speed allowed including frequency modulation (FM).
42 MHz parts allow for 40 MHz system clock + 2% FM; 68 MHz parts allow for a 66 MHz system clock + 2% FM, and
82 MHz parts allow for 80 MHz system clock + 2% FM.

The minimum SCK cycle time restricts the baud rate selection for the given system clock rate. These numbers are calculated based on two MPC55xx devices communicating over a DSPI link.

<sup>&</sup>lt;sup>4</sup> The actual minimum SCK cycle time is limited by pad performance.

<sup>&</sup>lt;sup>5</sup> The maximum value is programmable in DSPI\_CTARx[PSSCK] and DSPI\_CTARx[CSSCK].

<sup>&</sup>lt;sup>6</sup> The maximum value is programmable in DSPI\_CTARx[PASC] and DSPI\_CTARx[ASC].

<sup>&</sup>lt;sup>7</sup> This number is calculated using the SMPL\_PT field in DSPI\_MCR set to 0b10.

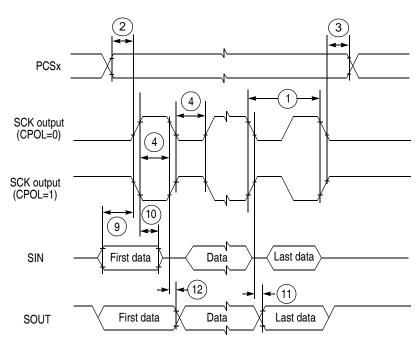


Figure 18. DSPI Classic SPI Timing—Master, CPHA = 0

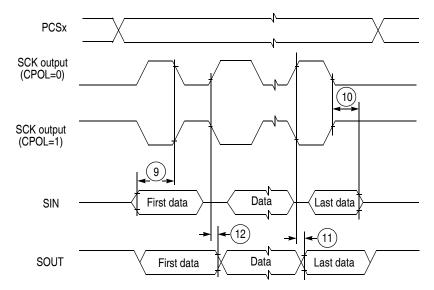


Figure 19. DSPI Classic SPI Timing—Master, CPHA = 1

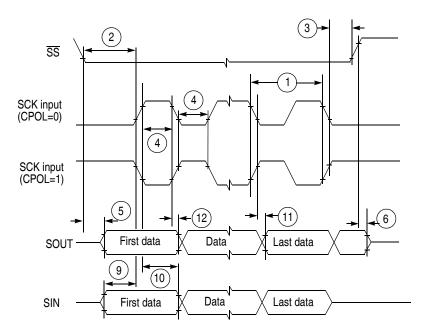


Figure 20. DSPI Classic SPI Timing—Slave, CPHA = 0

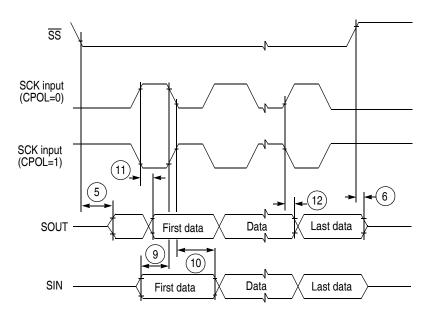


Figure 21. DSPI Classic SPI Timing—Slave, CPHA = 1

MPC5534 Microcontroller Data Sheet, Rev. 5

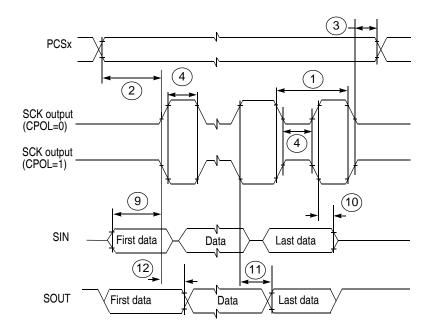


Figure 22. DSPI Modified Transfer Format Timing—Master, CPHA = 0

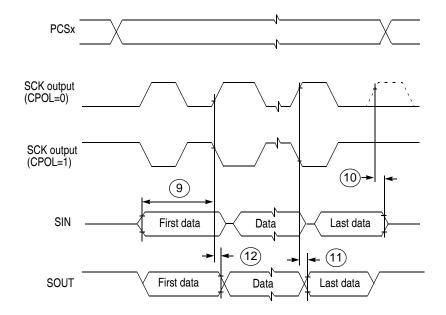


Figure 23. DSPI Modified Transfer Format Timing—Master, CPHA = 1

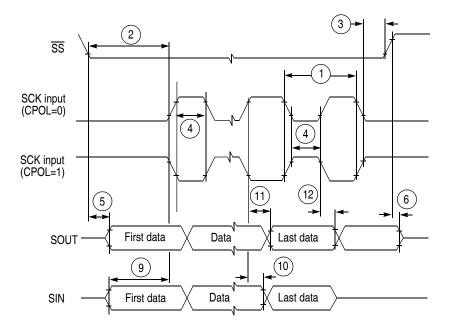


Figure 24. DSPI Modified Transfer Format Timing—Slave, CPHA = 0

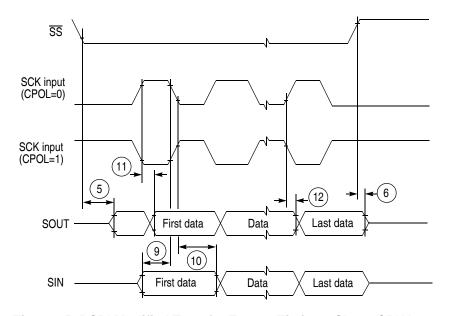


Figure 25. DSPI Modified Transfer Format Timing—Slave, CPHA = 1



Figure 26. DSPI PCS Strobe (PCSS) Timing

MPC5534 Microcontroller Data Sheet, Rev. 5

## 3.13.9 eQADC SSI Timing

**Table 27. EQADC SSI Timing Characteristics** 

| Spec | Rating   | Symbol              | Minimum                    | Typical | Maximum                         | Unit                 |
|------|--|---------------------|----------------------------|---------|---------------------------------|----------------------|
| 2    | FCK period $(t_{FCK} = 1 \div f_{FCK})^{1, 2}$ | t <sub>FCK</sub>    | 2                          | _       | 17                              | t <sub>SYS_CLK</sub> |
| 3    | Clock (FCK) high time                          | t <sub>FCKHT</sub>  | $t_{SYS\_CLK} - 6.5$       | _       | $9\times (t_{SYS\_CLK}+6.5)$    | ns                   |
| 4    | Clock (FCK) low time                           | t <sub>FCKLT</sub>  | t <sub>SYS_CLK</sub> - 6.5 | _       | $8 \times (t_{SYS\_CLK} + 6.5)$ | ns                   |
| 5    | SDS lead / lag time                            | t <sub>SDS_LL</sub> | -7.5                       | _       | +7.5                            | ns                   |
| 6    | SDO lead / lag time                            | t <sub>SDO_LL</sub> | -7.5                       | _       | +7.5                            | ns                   |
| 7    | EQADC data setup time (inputs)                 | t <sub>EQ_SU</sub>  | 22                         | _       | _                               | ns                   |
| 8    | EQADC data hold time (inputs)                  | t <sub>EQ_HO</sub>  | 1                          | _       | _                               | ns                   |

 $<sup>\</sup>overline{SS}$  timing specified at V<sub>DDEH</sub> = 3.0–5.25 V, T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>, and CL = 25 pF with SRC = 0b11. Maximum operating frequency varies depending on track delays, master pad delays, and slave pad delays.

<sup>&</sup>lt;sup>2</sup> FCK duty cycle is not 50% when it is generated through the division of the system clock by an odd number.

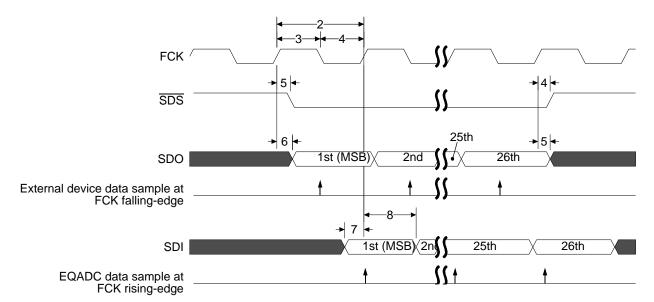


Figure 27. EQADC SSI Timing

## 4 Mechanicals

## 4.1 MPC5534 208 MAP BGA Pinout

Figure 28 is a pinout for the MPC5534 208 MAP BGA package.

### **NOTES**

 $V_{DDEH10}$  and  $V_{DDEH6}$  are connected internally on the 208-ball package and are listed as  $V_{DDEH6}$ .

The MPC5500 devices are pin compatible for software portability and use the primary function names to label the pins in the BGA diagram. Although some devices do not support all the primary functions shown in the BGA diagram, the muxed and GPIO signals on those pins remain available. See the signals chapter in the device reference manual for the signal muxing.

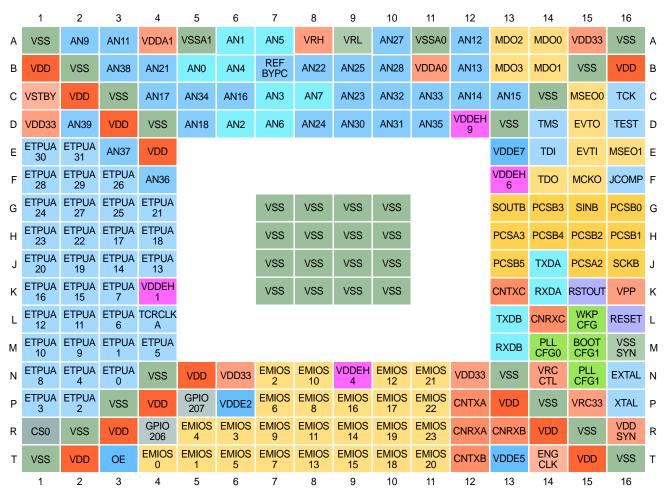


Figure 28. MPC5534 208 Package

MPC5534 Microcontroller Data Sheet, Rev. 5

#### 4.2 MPC5534 324 PBGA Pinouts

Figure 29 is a pinout for the MPC5534 324 PBGA package.

## NOTE

The MPC5500 devices are pin compatible for software portability and use the primary function names to label the pins in the BGA diagram. Although some devices do not support all the primary functions shown in the BGA diagram, the muxed and GPIO signals on those pins remain available. See the signals chapter in the device reference manual for the signal muxing.

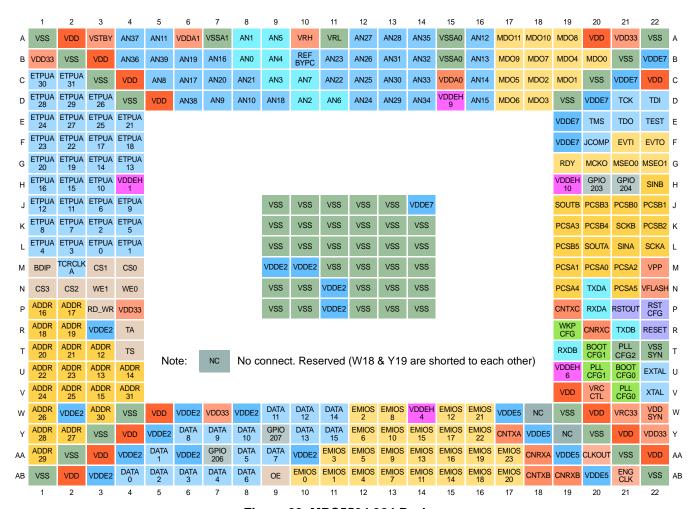
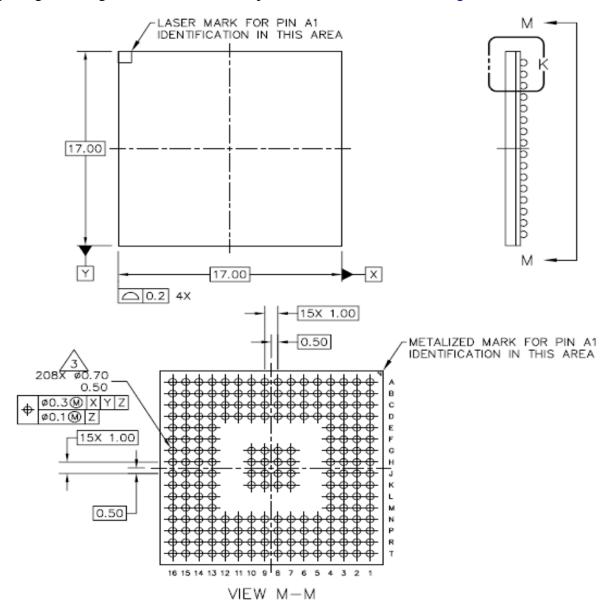


Figure 29. MPC5534 324 Package

Downloaded from **Elcodis.com** electronic components distributor

## 4.3 MPC5534 208-Pin Package Dimensions

The package drawings of the MPC5534 208-pin MAP BGA are shown in Figure 30.



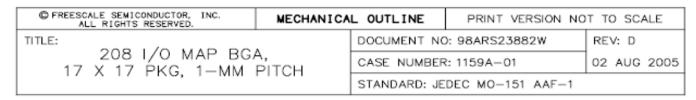
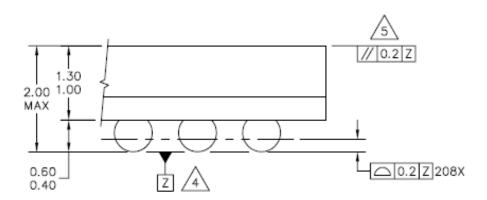


Figure 30. MPC5534 208-Pin Package

MPC5534 Microcontroller Data Sheet, Rev. 5



DETAIL K
(ROTATED 90' CLOCKWISE)

#### NOTES:

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.



JUMENSION B IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER, PARALLEL TO DATUM PLANE Z.



DATUM Z (SEATING PLANE) IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.



PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.

| © FREESCALE SEMICONDUCTOR, INC.  ALL RIGHTS RESERVED.  MECHANICA |  | L OUTLINE    | PRINT VERSION NO | T TO SCALE  |
|--|--|--------------|------------------|-------------|
| TITLE:  208 I/O MAP BGA,  17 X 17 PKG, 1-MM PITCH                |  | DOCUMENT NO  | ): 98ARS23882W   | REV: D      |
|  |  | CASE NUMBER  | : 1159A-01       | 02 AUG 2005 |
|  |  | STANDARD: JE | DEC MO-151 AAF-1 |             |

Figure 30. MPC5534 208 MAP BGA Package (continued)

MPC5534 Microcontroller Data Sheet, Rev. 5

## 4.4 MPC5534 324-Pin Package Dimensions

The package drawings of the MPC5534 324-pin TEPBGA package are shown in Figure 31.

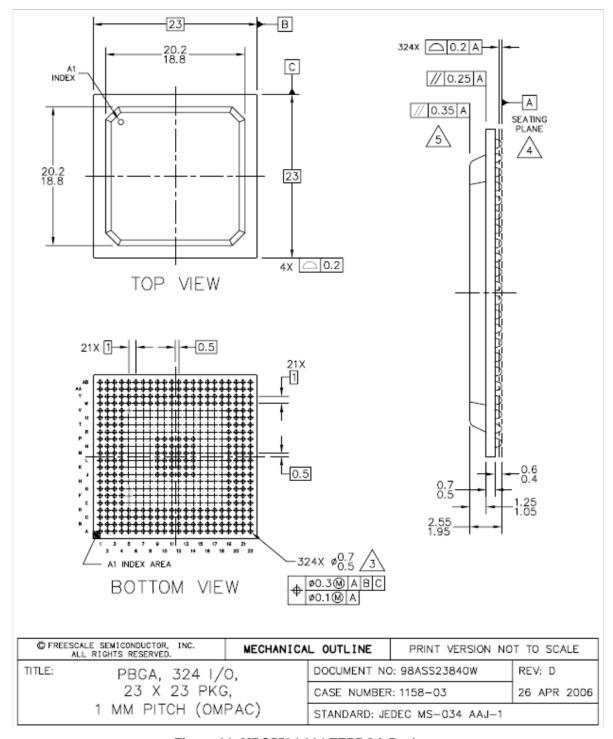


Figure 31. MPC5534 324 TEPBGA Package

MPC5534 Microcontroller Data Sheet, Rev. 5

### NOTES:

- 1. ALL DIMENSIONS IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.



MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.



DATUM A, THE SEATING PLANE, IS DETERMINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.



PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.

| © FREESCALE SEMICONDUCTOR, INC.  ALL RIGHTS RESERVED.  MECHANICAL |  | L OUTLINE    | PRINT VERSION NO | T TO SCALE  |
|---|--|--------------|------------------|-------------|
| TITLE: PBGA, 324 I/O,   |  | DOCUMENT NO  | ): 98ASS23840W   | REV: D      |
| ,   |  | CASE NUMBER  | 2: 1158–03       | 26 APR 2006 |
| 1 MM PITCH (OMPAC)  |  | STANDARD: JE | DEC MS-034 AAJ-1 |             |

Figure 31. MPC5534 324 TEPBGA Package (continued)

MPC5534 Microcontroller Data Sheet, Rev. 5

The history of revisions made to this data sheet are described in this section. The changes are divided into each revision of this document.

The substantive changes incorporated in MPC5534 Data Sheet revision 4.0 to produce revision 5.0 are:

- Text changes
- Table and figure changes

Within each group, the changes are listed in sequential page number order.

## 5.1 Changes Between Revisions 4.0 and 5.0

The following table lists the substantive text changes made to paragraphs.

Table 28. Text Changes Between Rev. 4.0 and 5.0

| Location    | Description of Changes   |
|-------------|--|
| Title page: |  |
|             | Changed the Revision number from 4.0 to 5.0. Changed the date format to DD MMM YYYY. Made the same changes in the lower left corner of the back page.  |
| Section 3.2 | .1, "General Notes for Specifications at Maximum Junction Temperature  |
|             | Updated the address of Semiconductor Equipment and Materials International 3081 Zanker Rd. San Jose, CA., 95134 (408) 943-6900   |
| Table 16 or | page 24  |
|             | Added footnote 9: For frequencies up to and including 80 MHz, if VDD is within ±5% of 1.5 V, then APC = RWSC = 0b010 is a valid setting.   |
| 4 Mechanic  | als:   |
|             | Added the following NOTE before the 208 and 324 BGA Maps:  NOTE  |
|             | The MPC5500 devices are pin compatible for software portability and use the primary function names to label the pins in the BGA diagram. Although some devices do not support all the primary functions shown in the BGA diagram, the muxed and GPIO signals on those pins remain available. See the signals chapter in the device reference manual for the signal muxing. |
| Section 3.7 | , "Power-Up/Down Sequencing  |
|             | Last paragraph: Changed the first sentence FROM the voltage on the pins goes to high-impedance until TOthe pins go to a high-impedance state until   |

# 5.2 Changes Between Revisions 3.0 and 4.0

The following table lists the substantive text changes made to paragraphs.

MPC5534 Microcontroller Data Sheet, Rev. 5

## Table 29. Text Changes Between Rev. 3.0 and 4.0

| Location    | Description of Changes   |
|-------------|--|
| Title Page: |  |
|             | Changed the Revision number from 3.0 to 4.0. Changed the date format to DD MMM YYYY. Made the same changes in the lower left corner of the back page.  |
| Section 1,  | "Overview":  |
|             | Added the sentence directly preceding Table 1: 'Unless noted in this data sheet, all specifications apply from $T_L$ to $T_H$ .'   |
| Sections 3  | 7.1, 3.7.2 and 3.7.3: Reordered sections resulting in the following order and section renumbering:   |
|             | <ul> <li>Section 3.7.1, "Input Value of Pins During POR Dependent on VDD33," then</li> <li>Section 3.7.2, "Power-Up Sequence (VRC33 Grounded)," then</li> <li>Section 3.7.3, "Power-Down Sequence (VRC33 Grounded).</li> </ul>   |
| Section 3.7 | 7.1, "Input Value of Pins During POR Dependent on VDD33:"  |
|             | Added the following text directly before this section and after Table 8 Pin Status for Medium and Slow Pads During the Power-on Sequence:  'The values in Table 7 and Table 8 do not include the effect of the weak pull devices on the output pins during power up.   |
|             | Before exiting the internal POR state, the voltage on the pins goes to high-impedance until POR negates. When the internal POR negates, the functional state of the signal during reset applies and the weak pull devices (up or down) are enabled as defined in the device <i>Reference Manual</i> . If V <sub>DD</sub> is too low to correctly propagate the |

Section 3.7.3, "Power-Down Sequence (VRC33 Grounded)" Deleted the underscore in ORed\_POR to become ORed POR.

To avoid this condition, minimize the ramp time of the  $V_{\mbox{\scriptsize DD}}$  supply to a time period less than the time required to

logic signals, the weak-pull devices can pull the signals to  $V_{DDE}$  and  $V_{DDEH}$ .

enable the external circuitry connected to the device outputs.'

MPC5534 Microcontroller Data Sheet, Rev. 5

The following table describes the changes made to information in tables and figures, and is presented in sequential page number order.

Table 30. Table and Figure Changes Between Rev. 3.0 and 4.0

## Location Description of Changes

## Figure 1, MPC5500 Family Part Numbers:

- Removed the 2 in the tape and reel designator in both the graphic and in the Tape and Reel Status text.
- Changed Qualification Status by adding ', general market flow' to the M designator, and added an 'S' designator with the description of 'Fully spec. qualified, automotive flow.

#### Table 1, Orderable Part Numbers:

- Footnote 1 added that reads: All devices are PPC5534, rather than MPC5534 or SPC5534, until product qualifications are complete. Not all configurations are available in the PPC parts.
- Reordered rows to group devices by lead-free package types in descending frequency order, and leaded package types.
- Footnote 2 added that reads:' The lowest ambient operating temperature is referenced by T<sub>L</sub>; the highest ambient operating temperature is referenced by T<sub>H</sub>.'
- Footnote 3 added that reads: 'Speed is the nominal maximum frequency. Max speed is the maximum speed allowed including frequency modulation (FM). 42 MHz parts allow for 40 MHz system clock + 2% FM; 68 MHz parts allow for 66 MHz system clock + 2% FM, and 82 MHz parts allow for 80 MHz system clock + 2% FM.'

### Table 2, Absolute Maximum Ratings:

- Deleted Spec 3, "Flash core voltage."
- Spec 12 "DC Input Voltage": Deleted from second line: . . . except for eTPUB[15] and SINB (DSPI\_B\_SIN)' leaving V<sub>DDEH</sub> powered I/O pads. Deleted third line 'V<sub>DDEH</sub> powered by I/O pads (eTPUB[15] and SINB), including the min. and max values of -0.3 and 6.5 respectively, and deleted old footnote 7.
- Spec 12 "DC Input Voltage": Added footnote 8 to second line "V<sub>DDE</sub> powered I/O pads" that reads: 'Internal structures hold the input voltage less than the maximum voltage on all pads powered by the V<sub>DDE</sub> supplies, if the maximum injection current specification is met (s mA for all pins) and V<sub>DDE</sub> is within the operating voltage specifications.
- Spec 14, column 2, changed: 'V<sub>SS</sub> differential voltage' to 'V<sub>SS</sub> to V<sub>SSA</sub> differential voltage.'
- Spec 15, column 2, changed: 'V<sub>DD</sub> differential voltage' to 'V<sub>DD</sub> to V<sub>DDA</sub> differential voltage.'
- Spec 21, Added the name of the spec, 'V<sub>RC33</sub> to V<sub>DDSYN</sub> differential voltage,' as well as the name and cross reference to Table 9, DC Electrical Specifications, to which the Spec was moved.
- Spec 28 "Maximum Solder Temperature": Added two lines:
   Lead free (PbFree) and Leaded (SnPb) with maximum values of 260 C and 245 C respectively.
- Footnote 1, added: 'any of' between 'beyond' and 'the listed maxima.'
- Deleted footnote 2: 'Absolute maximum voltages are currently maximum burn-in voltages. Absolute maximum specifications for device stress have not yet been determined.'Spec 26 "Maximum Operating Temperature Range": replaced -40 C with.
- Footnote 6 (now footnote 5): Changed the end of the last sentence as follows; "Internal structures hold the input voltage greater than -1.0 V if the injection current limit of 2 mA is met. Keep the negative DC voltage greater than -0.6 V on eTPU[15] and on SINB during the internal power-on reset (POR) state."

#### Table 3, MPC5534 Thermal Characteristics:

Changed for production purposes, footnote 1 from:

Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other *components on the board*, and board thermal resistance.

to:

Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other *board components*, and board thermal resistance.

#### MPC5534 Microcontroller Data Sheet, Rev. 5

## Table 30. Table and Figure Changes Between Rev. 3.0 and 4.0 (continued)

#### Location

### **Description of Changes**

Table 4, EMI Testing Specifications: Changed the maximum operating frequency from 82 to f<sub>MAX</sub>.

Table 6, VCR/POR Electrical Specifications:

- Added footnote 1 to specs 1, 2, and 3 that reads: On power up, assert RESET before V<sub>POR15</sub>, V<sub>POR33</sub>, and V<sub>POR5</sub> negate (internal POR). RESET must remain asserted until the power supplies are within the operating conditions as specified in Table 9 *DC Electrical Specifications*. On power down, assert RESET before any power supplies fall outside the operating conditions and until the internal POR asserts.
- Subscript all symbol names that appear after the first underscore character.
- Removed 'Tj ' after '150 C' in Spec 10, Characteristic column:
- Added footnote 1 to specs 1, 2, and 3 that reads: On power up, assert RESET before V<sub>POR15</sub>, V<sub>POR33</sub>, and V<sub>POR5</sub> negate (internal POR). RESET must remain asserted until the power supplies are within the operating conditions as specified in Table 9 *DC Electrical Specifications*. On power down, assert RESET before any power supplies fall outside the operating conditions and until the internal POR asserts.
- · Added to Spec 2:

 $3.3 \ V \ (V_{DDSYN}) \ POR \ negated \ (ramp \ down) \\ 3.3 \ V \ (V_{DDSYN}) \ POR \ asserted \ (ramp \ up) \\ Min \ 0.0 \\ Max \ 0.30 \ V \\ V_{DDSYN}$ 

- Spec 3: Added new footnote 3 for both lines: 'It is possible to reach the current limit during ramp up--do not treat this event as a short circuit current.'
- Spec 5: Changed old Footnote 1 (now footnote 2): 'User must be able to supply full operating current for the 1.5 V supply when the 3.3 V supply reaches this range." to 'Supply full operating current for the 1.5 V supply when the 3.3 V supply reaches this range."
- Specs 7 and 10: added 'at Tj ' at the end of the first line in the second column: Characteristic.
- Spec 10:
  - Added cross-reference to footnote 6:  $^{1}V_{RCCTL}$  is measured at the following conditions:  $^{1}V_{DD} = 1.35 \text{ V}$ ,  $^{1}V_{RC33} = 3.1 \text{ V}$ ,  $^{1}V_{VRCCTL} = 2.2 \text{ V}$ . Changed  $^{1}V_{DD} = 1.35 \text{ V}$ ,  $^{1}V_{SyS} = ^{1}V_{MAX}$ .
  - Added old footnote 5 new footnote 6.
  - Added a new footnote 7, 'Refer to Table 1 for the maximum operating frequency.'
  - Rewrote old footnote 8 (new footnote 9) to: Represents the worst-case external transistor BETA. It is measured
    on a per part basis and calculated as (I<sub>DD</sub> ÷ I<sub>VRCCTL</sub>).
- Deleted footnote 9 Preliminary value, Final specification pending characterization.

Table 7, Power Sequence Pin Status for Fast Pads: Changed title to Pin Status for Fast Pads During the Power Sequence

Table 8, Power Sequence Pin Status for Medium/Slow Pads:

- Changed title to Pin Status for Medium and Slow Pads During the Power Sequence
- Updated preceding paragraph.

#### Table 9, DC Electrical Specifications:

- Spelled out meaning of the slash '/' as 'and'. Still confusing. Deleted 'I/O' from the specs to improve clarity.
- Added footnote that reads: V<sub>DDE2</sub> and V<sub>DDE3</sub> are limited to 2.25–3.6 V only if EBTS = 0; V<sub>DDE2</sub> and V<sub>DDE3</sub> have a range of 1.6–3.6 V if EBTS =1.
- Spec 20, column 2, Characteristics,' Slow and medium output high voltage (I<sub>OH\_S</sub> = -2.0 mA):'
   Created a left-justified second line and moved 'I<sub>OH\_S</sub> = -2.0 mA' from the 1st line to the second line and deleted the parentheses. Created a left-justified third line that reads 'I<sub>OH\_S</sub> = -1.0 mA.'
- Spec 20, column 4, Min: Added a blank line before and after '0.80 × V<sub>DDEH</sub>' and put '0.85 × V<sub>DDEH</sub>' on the last line.
- Spec 22, column 2, 'Slow and medium output low voltage (I<sub>OL\_S</sub> = 2.0 mA):' Created a left-justified second line and moved 'I<sub>OL\_S</sub> = 2.0 mA.' from the 1st line to the second line and deleted the parentheses. Created a left-justified third line that reads 'I<sub>OL\_S</sub> = 1.0 mA.'
- Spec 22, column 5, Max: Added a blank line before and after '0.20 × V<sub>DDEH</sub>' and put '0.15 × V<sub>DDEH</sub>' on the last line.
- Spec 26: Changed 'AN[12]\_MA[1]\_SDO' to 'AN[13]\_MA[1]\_SDO'.
- Spec 28: Changed 82 MHz to f<sub>MAX</sub> MHz.
- Footnote 9: Changed from 'Preliminary. Final specification pending characterization.' to 'Figure 3 shows an illustration of the I<sub>DD\_STBY</sub> values interpolated for these temperature values.'

MPC5534 Microcontroller Data Sheet, Rev. 5

## Table 30. Table and Figure Changes Between Rev. 3.0 and 4.0 (continued)

#### Location

#### **Description of Changes**

#### Table 12, FMPLL Electrical Characteristics:

- Spec 1, footnote 1 in column 2: 'PLL reference frequency range': Added that reads 'Nominal crystal and external reference values are worst-case not more than 1%. The device operates correctly if the frequency remains within ± 5% of the specification limit. This tolerance range allows for a slight frequency drift of the crystals over time. The designer must thoroughly understand the drift margin of the source clock.'
- Spec 1, footnote 2 in column 1: Changed to: 'The 8–20 MHz crystal or external reference values have PLLCFG[2] pulled low' and applies to spec 1, column 2, crystal reference and external reference.
- Spec 21, column 2: Changed  $f_{ref\_crystal}$  to  $f_{ref}$  in ICO frequency equation, and added the same equation but substituted  $f_{ref\_ext}$  for  $f_{ref}$  for the external reference clock, giving:  $f_{ico} = [f_{ref\_crystal} \times (MFD + 4)] \div (PREDIV + 1)$   $f_{ico} = [f_{ref\_ext} \times (MFD + 4)] \div (PREDIV + 1)$
- Spec 21: Changed column 5 from 'f<sub>SYS</sub>' MHz' to: 'f<sub>MAX</sub>'.
- Spec 22: Changed column 4, Max Value from f<sub>MAX</sub> to 20, and added footnote 17 to read, 'Maximum value for dual controller (1:1) mode is (f<sub>MAX</sub> ÷ 2) and the predivider set to 1 (FMPLL\_SYNCR[PREDIV] = 0b001).'

Table 13, eQADC Conversion Specifications: Changed '(Operating)' to ' $(T_A = T_L - T_H)$ ' to the table title.

## Table 14, Flash Program and Erase Specifications:

- Added  $(T_A = T_L T_H)$  to the table title.
- Spec 8, 128 KB block pre-program and erase time, Max column value from 15,000 to 7,500.
- Moved footnote 1 from the table title to directly after the 'Typical' in the column 5 header.
- Footnote 2: Changed from: 'Initial factory condition: ≤ 100 program/erase cycles, 25 °C, typical supply voltage, 80 MHz minimum system frequency.' To: 'Initial factory condition: ≤ 100 program/erase cycles, 25 °C, using a typical supply voltage measured at a minimum system frequency of 80 MHz.'

#### Table 15, Flash EEPROM Module Life:

- Replaced (Full Temperature Range) with (T<sub>A</sub> = T<sub>L</sub> T<sub>H</sub>) in the table title.
- Spec 1b, Min. column value changed from 10,000 to 1,000.

### Table 16, FLash BIU Settings vs. Frequency of Operations:

- 'Added footnote 1 to the end of the table title, The footnote reads: 'Illegal combinations exist. Use entries from the same row in this table.'
- Moved footnote 2:' For maximum flash performance, set to 0b11' to the 'DPFEN' column header.
- Deleted the x-refs in the 'DPFEN' column for the rows.
- Created a x-ref for footnote 2 and inserted in the 'IPFEN' column header.
- Deleted the x-refs in the 'IPFEN' column for the rows.
- Added to the PFLIM binary values a leading 0 so that 0bxx became 0b0xx.
- Moved footnote 3:' For maximum flash performance, set to 0b110' to the 'PFLIM' column header.
- Deleted the x-refs in the 'PFLIM' column for the rows.
- Moved footnote 4:' For maximum flash performance, set to 0b1' to the 'BFEN' column header.
- Deleted the x-refs in the 'BFEN' column for the rows.
- Added footnotes 4, 6, 7, and 8:
  - -- footnote 4 27 MHz parts allow for 25 MHz system clock + 2% frequency modulation (FM).
  - -- footnote 5 52 MHz parts allow for 50 MHz system clock + 2% FM.
  - -- footnote 6 77 MHz parts allow for 75 MHz system clock + 2% FM.
  - -- footnote 7 82 MHz parts allow for 80 MHz system clock + 2% FM.

MPC5534 Microcontroller Data Sheet, Rev. 5

Freescale Semiconductor

56

57

## Table 30. Table and Figure Changes Between Rev. 3.0 and 4.0 (continued)

#### Location

#### **Description of Changes**

Table 17, Pad AC Specifications, and Table 18, Derated Pad AC Specifications: The changes are identical in the tables.

- Table 17, Pad AC Specifications only: Footnote 1, changed 'V<sub>DDEH</sub> = 4.5–5.5;' to 'V<sub>DDEH</sub> = 4.5–5.25;'
- Footnote 1, deleted 'F<sub>SYS</sub> = 80 MHz'
- Footnote 2, changed from 'tested' to '(not tested).'
- Footnote 3, changed from 'Out delay. . .' to 'The output delay. . .',
- Changed from 'Add a maximum of one system clock to the output delay to get the output delay with respect to
  the system clock' to 'To calculate the output delay with respect to the system clock, add a maximum of one system
  clock to the output delay.'
- Footnote 4: changed 'Delay' to 'The output delay.'
- Footnote 5: deleted 'before qualification.'
- Changed from 'This parameter is supplied for reference and is not guaranteed by design and not tested' to 'This parameter is supplied for reference and is guaranteed by design and tested.'

Table 19, Reset and Configuration Pin Timing: Footnote 1, deleted 'F<sub>SYS</sub> = 80 MHz.'

Table 20, JTAG Pin AC Electrical Characteristics:

- Footnote 1, deleted: ', and CL = 30 pF with DSC = 0b10, SRC = 0b11'
- · Footnote 1, changed 'functional' to 'Nexus.'

### Table 21, Nexus Debug Port Timing.

Changed Spec 12, TCK Low to TDO Data Valid: Changed 'VDDE = 3.0 to 3.6 volts' maximum value in column 4 from 9 to 10. Now reads 'V<sub>DDE</sub> = 3.0–3.6 V' with a max value of 10.

#### Table 22, Bus Operation Timing:

- External Bus Frequency: Added footnote that reads: Speed is the nominal maximum frequency. Max speed is
  the maximum speed allowed including frequency modulation (FM). 42 MHz parts allow for 40 MHz system clock
  + 2% FM; 68 MHz parts allow for 66 MHz system clock + 2% FM, and 82 MHz parts allow for
  80 MHz system clock + 2% FM.
- Spec 1: Changed the system frequency columns from 40, 56, and 66 MHz to 20, 33, and 40 MHz. Changed the values in Min. columns: 20 MHz from 25 to 24.4; 33 MHz from 17.9 to 17.5, and 40 MHz from 15.2 to 14.9.
- Specs 5 and 6: CLKOUT positive edge to output signals invalid of high: Corrected format to show the bus timing values for various frequencies with EBTS bit = 0 and EBTS bit = 1.
- Specs 5 and 6: Changed the following calibration signals: CAL\_ADDR[8:30] to CAL\_ADDR[10:30], and CAL\_WE/BE[0:1] to CAL\_WE[0:1]. Deleted TEA.
- Specs 7 and 8: Changed the following calibration signals: CAL\_ADDR[8:30] to CAL\_ADDR[10:30]. Deleted TEA.
   BDIP, OE, RD\_WR, and WE/BE[0:1]. CAL\_CS[0, 2:3], CAL\_OE, CAL\_RD\_WR, and CAL\_WE/BE[0:1].

### Table 23, External Interrupt Timing:

- Footnote 1: Changed ' $V_{DDEH} = 3.0-5.5$ ;' to ' $V_{DDEH} = 3.0-5.25$ ;'
- Footnote 1: Deleted ' $F_{SYS}$  = 80 MHz.', ' $V_{DD}$  = 1.35–1.65 V', ' $V_{DD33}$  and  $V_{DDSYN}$  = 3.0–3.6 V.' and 'and CL = 200 pF with SRC = 0b11.'
- Deleted second figure after table 'External Interrupt Setup Timing.'

## Table 24, eTPU Timing

- Footnote 1: Changed ' $V_{DDEH} = 3.0-5.5$ ;' to ' $V_{DDEH} = 3.0-5.25$ ;'
- Footnote 1: Deleted 'F<sub>SYS</sub> = 80 MHz.', 'V<sub>DD</sub> = 1.35–1.65 V', 'V<sub>DD33</sub> and V<sub>DDSYN</sub> = 3.0–3.6' and 'and CL = 200 pF with SRC = 0b11.'
- Deleted second figure, 'eTPU Input/Output Timing' after this table.
- Added Footnote 2: 'This specification does not include the rise and fall times. When calculating the minimum eTPU pulse width, include the rise and fall times defined in the slew rate control fields (SRC) of the pad configuration registers (PCR).'

MPC5534 Microcontroller Data Sheet, Rev. 5

## Table 30. Table and Figure Changes Between Rev. 3.0 and 4.0 (continued)

#### Location

#### **Description of Changes**

## Table 25, eMIOS Timing:

- · Deleted (MTS) from the heading, table, and footnotes.
- Footnote 1: Changed 'V<sub>DDEH</sub> = 3.0–5.5;' to 'V<sub>DDEH</sub> = 3.0–5.25;'
- Footnote 1: Deleted ' $F_{SYS}$  = 80 MHz,' ' $V_{DD}$  = 1.35–1.65 V', ' $V_{DD33}$  and  $V_{DDSYN}$  = 3.0–3.6 V' and 'and CL = 200 pF with SRC = 0b11.'
- Added Footnote 2: 'This specification does not include the rise and fall times. When calculating the minimum eMIOS pulse width, include the rise and fall times defined in the slew rate control fields (SRC) of the pad configuration registers (PCR).'

## Figure 17, eMIOS Timing: Added figure.

#### Table 26, DSPI Timing:

- Table Title: Added footnote that reads: Speed is the nominal maximum frequency. Max speed is the maximum speed allowed including frequency modulation (FM). 42 MHz parts allow for 40 MHz system clock + 2% FM; 68 MHz parts allow for 66 MHz system clock + 2% FM, and 82 MHz parts allow for 80 MHz system clock + 2% FM.
- Spec1: SCK Cycle Time: changes to values: 40 MHz, min. = 48.8 ns, max = 5.8 ms; 66 MHz, min. = 28.4 ns, max = 3.5 ms; 80 MHz min. = 24.4 ns, max = 2.9 ms.
- Spec 2: PCS to SCK delay: 40 MHz, min. = 46 ns; 66 MHz, min. = 26 ns; 80 MHz min. = 22 ns.
- Spec 3: After SCK delay: 40 MHz, min. = 45 ns; 66 MHz, min. = 25 ns; 80 MHz min. = 21 ns.
- Spec 9: Data setup time for inputs, Master (MTFE = 1, CPHA = 0): 66 MHz, min. = 6 ns; 80 MHz min. = 8 ns.
- Spec 10: Data hold time for inputs, Master (MTFE = 1, CPHA = 0): 40 MHz, min. = 45 ns; 66 MHz, min. = 25 ns; 80 MHz min. = 21 ns.
- Spec 11: Data valid (after SCK edge), Master (MTFE = 1, CPHA = 0): 40 MHz, max. = 45 ns;
   66 MHz, max. = 25 ns; 80 MHz max. = 21 ns.
- Footnote 1: Changed 'V<sub>DDEH</sub> = 3.0–5.5;' to 'V<sub>DDEH</sub> = 3.0–5.25;'
- Footnote 1: Added to beginning of footnote 1 'All DSPI timing specifications use the fastest slew rate (SRC = 0b11) on pad type M or MH. DSPI signals using pad types of S or SH have an additional delay based on the slew rate.'
- Footnote 1: Deleted ' $V_{DD}$  = 1.35–1.65 V' and ' $V_{DD33}$  and  $V_{DDSYN}$  = 3.0–3.6 V.

### Table 27, EQADC SSI Timing Characteristics:

- Footnote 1: Changed 'V<sub>DDEH</sub> = 3.0–5.5;' to 'V<sub>DDEH</sub> = 3.0–5.25;'
- Deleted from table title '(Pads at 3.3 V or 5.0 V)'
- Deleted 1st line in table 'CLOAD = 25 pF on all outputs. Pad drive strength set to maximum.'
- Spec 1: FCK frequency -- removed.
- Combined footnotes 1 and 2, and moved the new footnote to Spec 2. Moved old footnote 3 that is now footnote 2 to Spec 2.
- Footnote 1, deleted 'V<sub>DD</sub> = 1.35–1.65 V' and 'V<sub>DD33</sub> and V<sub>DDSYN</sub> = 3.0–3.6V.'
   Changed 'CL = 50 pF' to 'CL = 25 pF.'
- Footnote 2: added 'cycle' after 'duty' to read: FCK duty cycle is not 50% when . . . .

Figure 28, MPC5534 208 Package and Figure 29 MPC5534 324 Package: Deleted the version number and date.

Figure 30, MPC5534 208 Package Dimensions and Figure 31 MPC5534 324 Package Dimensions:

Deleted the version number and date.

MPC5534 Microcontroller Data Sheet, Rev. 5

Freescale Semiconductor

58

MPC5534 Microcontroller Data Sheet, Rev. 5

#### How to Reach Us:

**Home Page:** 

www.freescale.com

Web Support:

http://www.freescale.com/support

**USA/Europe or Locations Not Listed:** 

Freescale Semiconductor, Inc.
Technical Information Center, EL516
2100 East Elliot Road
Tempe, Arizona 85284
+1-800-521-6274 or +1-480-768-2130
www.freescale.com/support

Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH Technical Information Center Schatzbogen 7 81829 Muenchen, Germany +44 1296 380 456 (English) +46 8 52200080 (English) +49 89 92103 559 (German) +33 1 69 35 48 48 (French) www.freescale.com/support

#### Japan:

Freescale Semiconductor Japan Ltd. Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku, Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

#### Asia/Pacific:

Freescale Semiconductor China Ltd. Exchange Building 23F No. 118 Jianguo Road Chaoyang District Beijing 100022 China +86 10 5879 8000 support.asia@freescale.com

For Literature Requests Only: Freescale Semiconductor Literature Distribution Center 1-800-441-2447 or 303-675-2140 Fax: 303-675-2150 LDCForFreescaleSemiconductor@hibbertgroup.com

Document Number: MPC5534

Rev. 5 10/2010 Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals", must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

Freescale<sup>™</sup> and the Freescale logo are trademarks of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners.

© Freescale Semiconductor, Inc. 2008, 2010. All rights reserved.

RoHS-compliant and/or Pb-free versions of Freescale products have the functionality and electrical characteristics as their non-RoHS-compliant and/or non-Pb-free counterparts. For further information, see <a href="http://www.freescale.com">http://www.freescale.com</a> or contact your Freescale sales representative.

For information on Freescale's Environmental Products program, go to http://www.freescale.com/epp.

